OMRON



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Welcome to the Omron Components Catalogue

Omron Components is a world-class business delivering a wide range of high quality, high performance components utilising latest technologies and backed by full technical, applications and logistical support.

We offer the widest range of relays for power, signal and automotive applications as well as solid-state and MOSFET relays. Our G3VM MOSFETS combine



the advantages of mechanical and solid-state technologies allowing design flexibility with either AC or DC load able to be connected in either direction. We are also developing our range of microsensors, and currently offer photomicrosensors and a new range of D8M-D8 micro pressure-sensors which meet stringent safety standards such as working reliably with low pressure, metal casing and flange fitting. Our broad range of switches includes micro, DIP, and tactile options, and you will find a wide selection of connectors to meet



industry-standard data interconnect, power transmission and signalling. Omron Double Reflection LEDs feature built-in optical light guide technology that more than doubles effective light output compared with conventional bullet-type LEDs.

Environmental research and experience enabled us to formulate a policy to remove recognised hazardous substances from our products well within the timescales of European Directives. We have identified suitable alternative materials and agreed the changes we need to make to our production processes in order to maintain quality levels. All of our manufacturing sites have achieved ISO14001 certification for the management of environmental protection in our organisation.





Using our website alongside this catalogue, you can be kept fully up-to-date with our range of products, technical capabilities and environmental policy.

www.eu.omron.com/ocb

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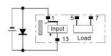
OMRON

Technical Information – MOSFET Relays

OMROD

Precautions

If any reversed surge voltage is imposed on the input terminals, insert a diode in parallel to the input terminals as shown in the following circuit diagram and do not impose a reversed voltage value of 3 V or more.



Terminals

Since terminals are made of materials with high heat conduction, complete soldering (automatic or manual) within 10 seconds at a temperature of 260°C.

When fitting with a Socket, match properly and push straight down vertically.

■ Introduction

New models and a wider range provide an array of solutions, meeting the needs of today's high performance applications.

Our new range of MOSFET relays, Type G3VM, set the benchmark in Solid State Relays (SSRs). Products are manufactured using the latest advances in automated production and include a variety of improved construction technologies within the areas of the input LED, PDA (Photo Diode Array used as a photocoupler) and MOSFET chips used in the load switching circuit. As a result, further reductions in package size and power requirements have been achieved.

Combining the advantages of mechanical and solid state technology, the new G3VM range gives you unprecedented capability to design. All models featured include a double MOSFET load circuit, enabling the designer complete versatility since it makes no difference whether an AC or DC load in either direction is connected (Connection A). Thus, the MOSFET relay is a fully functional alternative to an electromechanical relay with minimal additional drive circuitry.

The built-in Current Limit Function (CLR models) has many uses. Traditionally used to clamp excessive over current fault conditions in telecom equipment, this feature can also be used to good effect to resist transient and short circuit conditions.

MOSFET relays are the ideal data and telecommunication solution for line seizing, line switching, hook switching, Data Access Arrangement (DAA) function, line transformer circuit control and other feature phone functions. Central office applications require high reliability and long life. Here G3VM is ideal for use in the areas of Subscriber Line Interfaces (SLICs) Multiplexers and Routers. In addition, Local Area Networks (LANs) and Network Termination Units (NTUs) including Set-Top Boxes (STBs) and Remote Metering Systems (RMS) can take advantage of the G3VMs' small size and low ON resistance.

Advances in performance and cost reduction enable MOSFET relays to be considered as good alternatives to Reed Relays in application areas such as security motion detectors (standard and anti-mask PIRs), other surveillance alarm equipment and associated systems.

■ Glossary

Term	Symbol	Description
LED forward current	I _F	Rated current that can flow continuously in the forward direction of the LED
Repetitive peak LED forward current	I _{FP}	Rated current that can flow momentarily in the forward direction of the LED
LED forward current reduction rate	<i<sub>ON/°C</i<sub>	Rated change of forward current flowing through the LED relative to ambient temperature above 25 $^{\circ}\text{C}$
LED reverse voltage	V _R	Rated reverse voltage that can be applied between the anode and the cathode
Connection temperature	TJ	Rated temperature that can be allowed in the junction of the LED, Photodetector or MOSFET(s)
Output dielectric strength	V _{OFF}	Rated voltage that can be applied between the MOSFET's output terminals in the OFF state
Continuous load current	Io	Rated current that can flow between the MOSFET's output terminals in the ON state
ON current reduction rate	<i<sub>ON/°C</i<sub>	Rated change of load current flowing between MOSFET(s) output terminals relative to ambient temperature above 25 $^{\circ}\mathrm{C}$
Dielectric strength between input and output	V _{I-O}	Isolation voltage between input and output terminals for a specified time
Operating temperature	Ta	Ambient temperature range in which the relay may be operated without impairment
Storage temperature	T _{stg}	Ambient temperature range in which the relay may be stored while not operating
LED forward voltage	V _F	Voltage drop between the LED's anode and cathode at a certain forward current
LED reverse current	I _R	Leakage current flowing in the LED's reverse direction (between cathode and anode)
Capacity between LED terminals	C _T	Electrostatic capacitance between the anode and the cathode terminals of the LED
Trigger LED forward current	I _{FT}	Minimum value of input current necessary to put the output MOSFET(s) in to the ON state
Maximum resistance with output ON	R _{ON}	Resistance between the MOSFET's output terminals specified with reference to ON state current
Current leakage when the relay is open	I _{LEAK}	Leakage current flowing between the MOSFET's output terminals in the OFF state
Capacity between I/O terminals	C _{I-O}	Electrostatic capacitance between the input and output terminals of the relay
Insulation resistance	R _{I-O}	Resistance between the input and output terminals at the specified voltage value
Turn-ON time	tON	Time required for the output waveform to change from 0(100%) to 90(10%) after input goes from OFF to ON state
Turn-OFF time	tOFF	Time required for the output waveform to change from 0(100%) to 90(10%) after input goes from ON to OFF state
Output dielectric strength	V _{DD}	Rated load voltage that can be applied between the MOSFET's output terminals

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ALL DIMENSIONS SHOWN ARE IN MILLIMETERS.

To convert millimeters into inches, multiply by 0.03937. To convert grams into ounces, multiply by 0.03527.

Precautions -

 \bigwedge

WARNING

Be sure to turn OFF the power when wiring the relay, otherwise an electric shock may be received.

WARNING

Do not touch the charged terminals of the SSR, otherwise an electric shock may be received.

CAUTION

Do not apply overvoltage or overcurrent to the I/O circuits of the SSR, otherwise the SSR may malfunction or burn.

CAUTION

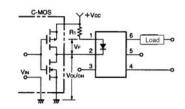
Be sure to wire and solder the Relay under the proper soldering conditions, otherwise the Relay in operation may generate excessive heat and the Relay may burn.

CAUTION

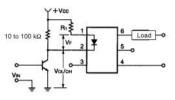
Electrostatic sensitive devices. Keep in original packaging until required to use. Avoid touching device terminals. Take static handling precaustions during processing.

Typical Relay Driving Circuit Examples

C-MOS



Transistor



Use the following formula to obtain the LED current limiting resistance value to assure that the relay operates accurately.

$$R_1 = \frac{V_{CC} - V_{OL} - V_F (ON)}{5 \text{ to 20 mA}}$$

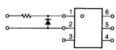
Use the following formula to obtain the LED forward voltage value to assure that the relay releases accurately.

$$V_{F (OFF)} = V_{CC} - V_{OH} < 0.8 \text{ V}$$

PROTECTION FROM SURGE VOLTAGE ON THE INPUT TERMINALS

If any reversed surge voltage is imposed on the input terminals, insert a diode in parallel to the input terminals as shown in the following circuit diagram and do not impose a reversed voltage value of 3 V or more.

Surge Voltage Protection Circuit Example



R_{cN} (Ω) Maximum rated value of R_{oN} Measured value of I_{FT} 10 I_F (mA)

Relationship between Ron and IFT

PRECAUTIONS WHEN MOUNTING DEVICES ON PCBS

Soldering

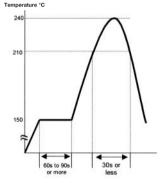
As far as it is possible, avoid raising the temperature of the device by observing the following restrictions.

Soldering leads directly

260°C max. 10 seconds max

Reflow soldering

- a) Lead temperature: 210°C max, 30 seconds max Atmospheric temperature close of mold body surface: 240°C max, 10 seconds max
- b) Recommended temperature profile



c) Precautions when heating

The soldering time (as shown above) must be kept as short as possible.

When using a halogen lamp of infrared heater, please do not irradiate the mold body surface directly.

Dip soldering (flow soldering)

Reflow soldering is recommended because the thermal stress involved is much less than that inherent in other soldering methods

If you plan to use dip soldering, please contact OMRON first.

Cleaning

When ions in the flux enter into the product during soldering, fluctuation in device performance or corrosion may occur. Be sure to wash away any flux residue which contains $C\ell$ or Na ions.

The following types of solvents are recommended for cleaning the flux

Asahi Clean AK-225AES

Kao Cleanthru 750H

Pine-Alpha ST-100S

Cleaning Conditions

Cleaning conditions and precautions may vary according to product specifications.

a) General precautions for dip cleaning

Dipping time varies according to the solvent used.

However, as a general guideline, it is recommended that the dip time be limited to three minutes.

b) General precautions for ultrasoni cleaning

When ultrasonic cleaning is conducted for an excessively long time, contact between the product resin and the metal leads may lessen. Also, excessive ultrasonic stress may cause cracks in the pellet.

It is recommended that the applied stress be minimized.

Recommended conditions for standard ultrasonic cleaning

Frequency: 27kHz to 29kHz
Output: 0.25 W/cm² or less
Time: 30 seconds or less

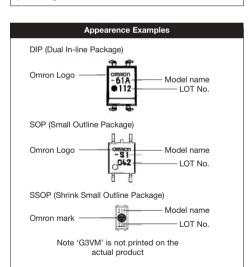
Temperature: 50°C (may vary according to the type of solvent

used

Cleaning must be conducted with the printed circuit board or device floating on the solvent, so as to avoid direct contact between the PCB or device and the ultrasonic vibrator.

Handling Precautions

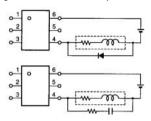
Do not touch the device's mark-bearing surface with your hand or with a brush while cleaning or applying cleaning liquid to the device. This may erase device markings. It is important to confirm that neither the solvent used for cleaning nor the cleaning conditions will damage the device package.



PROTECTION FROM SPIKE VOLTAGE ON THE OUTPUT TERMINALS

If a spike voltage exceeding the absolute maximum rated value is generated between the output terminals, insert a C-R snubber or clamping diode in parallel to the load as shown in the following circuit diagram to limit the spike voltage.

Spike Voltage Protection Circuit Example



UNUSED TERMINALS (6-PIN MODELS ONLY)

Terminal 3 is connected to thr internal circuit. Do not connect anything to terminal 3 externally.

PIN STRENGTH FOR AUTOMATIC MOUNTING

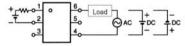
In order to maintain the characteristics of the relay, the force imposed on any pin of a relay for automatic mounting must not exceed the following.

In direction A: 1.96 N In direction B: 1.96 N

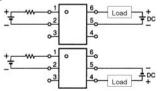
LOAD CONNECTION

Do not short-circuit the input and output terminals while the relay is operating or the relay may malfunction.

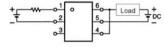
AC Connection



DC Single Connection



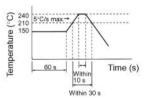
DC Parallel Connection



SOLDER MOUNTING

Maintain the following conditions during manual or reflow soldering of the relays in order to prevent the temperature of the relays from rising.

- 1. Pin Soldering
- Solder each pin at a maximum temperature of 260°C within 10 s.
- 2. Reflow Soldering
- a. Solder each pin at a maximum temperature of 260°C within
- b. Make sure that the ambient temperature on the surface of the resin casing is 240C max. for 10 s maximum.
- c. The following temperature changes are recommendable for soldering.

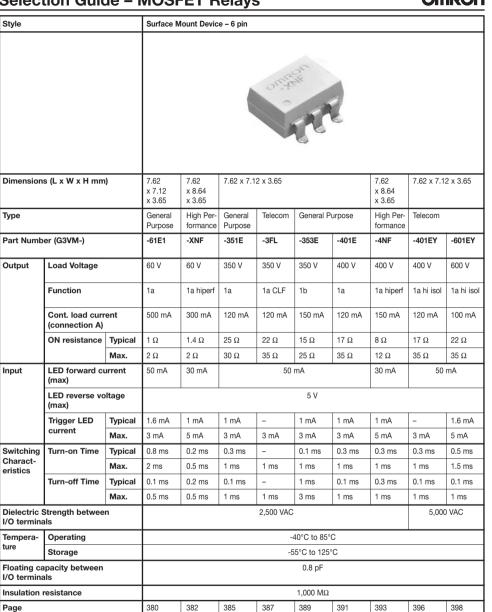


Selection Guide - MOSFET Relays

Style	Through	-hole Devi	ice – 4 pin			Surface Mount Device - 4 pin						
				0		1						
Dimension	s (L x W x H mm	1)	7.62 x 4.	58 x 3.65				7.62 x 4.5	58 x 3.65			
Туре			General F	Purpose	Telecom	General	Purpose	General F	ourpose	Telecom	General F	ourpose
Part Numb	er (G3VM-)		-61A1	-351A	-2L	-353A	-401A	-61D1	-351D	-2FL	-353D	-401D
Output	Load Voltage		60 V	350 V	350 V	350 V	400 V	60 V	350 V	350 V	350 V	400 V
	Function		1a	1a	1a CLF	1b	1a	1a	1a	1a CLF	1b	1a
	Cont. load curr (connection A)	rent	500 mA	120 mA	120 mA	150 mA	120 mA	500 mA	120 mA	120 mA	150 mA	120 mA
	ON resistance	Typical	1 Ω	35 Ω	22 Ω	15 Ω	18 Ω	1 Ω	35 Ω	22 Ω	15 Ω	18 Ω
		Max.	2 Ω	50 Ω	35 Ω	25 Ω	35 Ω	2 Ω	50 Ω	35 Ω	25 Ω	35 Ω
Input	LED forward co	urrent	50 mA				50 mA					
	LED reverse vo (max)	oltage	5	V	6 V	5 V		5 V		6 V	5 V	
	Trigger LED	Typical	1.6 mA	1 mA	1 mA	1 mA	1 mA	1.6 mA	1 mA	1 mA	1 mA	1 mA
	current	Max.	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA
Switching	Turn-on Time	Typical	0.8 ms	0.3 ms	-	1 ms	-	0.8 ms	0.3 ms	-	1 ms	-
Charact- eristics		Max.	2 ms	1 ms	1 ms	1 ms	1 ms	2 ms	1 ms	1 ms	1 ms	1 ms
	Turn-off Time	Typical	0.1 ms	0.1 ms	-	1 ms	-	0.1 ms	0.1 ms	-	1 ms	-
		Max.	0.5 ms	1 ms	1 ms	3 ms	1 ms	0.5 ms	1 ms	1 ms	3 ms	1 ms
Dielectric S I/O termina	Strength betwee als	n			2,500 VAC	;				2,500 VAC	;	
Tempera-	Operating			-	40°C to 85°	°C				40°C to 85°	°C	
ture	Storage			-5	55°C to 125	5°C			-5	55°C to 125	°C	
Floating ca	pacity between				0.8 pF					0.8 pF		
Insulation	resistance				1,000 ΜΩ					1,000 ΜΩ		
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Select	tion Guid	<u> 10 – 1</u>	MOSFE	ı Kelay	/S			OHIKOH		
Style			Small Outline F	Package - 4 pir	1					
				4	67	unaon (Ł			
Dimension	s (L x W x H mm)	7 x 3.9 x 2.1							
Туре			General Purpos	e						
Part Numb	er (G3VM-)		-61G1	-81G1	-201G	-351G	-353G	-401G		
Output	Load Voltage		60 V	80 V	200 V	350 V	350 V	400 V		
	Function		1a	1a	1a	1a	1b	1a		
	Cont. load curr (connection A)	ent	400 mA	350 mA	50 mA	110 mA	120 mA	120 mA		
	ON resistance	Typical	1 Ω	1 Ω	40 Ω	35 Ω	15 Ω	17 Ω		
		Max.	2 Ω	1.2 Ω	50 Ω	50 Ω	25 Ω	35 Ω		
Input	LED forward co	urrent	50 mA							
	LED reverse vo (max)	ltage		5 V						
	Trigger LED	Typical	1.6 mA	1 mA	1 mA	1 mA	1 mA	1 mA		
	current	Max.	3 mA	4 mA	3 mA	3 mA	3 mA	3 mA		
Switching Charact-	Turn-on Time	Typical	0.8 ms	0.3 ms	-	1 ms	-	0.3 ms		
eristics		Max.	2 ms	1 ms	1 ms	1 ms	1 ms	1 ms		
	Turn-off Time	Typical	0.1 ms	0.1 ms	-	1 ms	-	0.1 ms		
		Max.	0.5 ms	1 ms	1 ms	3 ms	1 ms	1 ms		
Dielectric S I/O termina	Strength betwee	n	1,500 VAC							
Tempera-	Operating				-41	0°C to 85°C				
ture	Storage				-55	°C to 125°C				
Floating ca	pacity between als					0.8 pF				
Insulation	resistance					1,000 MΩ				
Page			368	370	372	374	376	378		

Style			Through-hole Device – 6 pin									
								1				
Dimension	s (L x W x H mm	1)	7.62 x 7.12 x 3.65	7.62 x 8.64 x 3.65	7.62 x 7.1	2 x 3.65			7.62 x 8.64 x 3.65	7.62 x 7.1	2 x 3.65	
Туре			General Purpose	High Per- formance	General Purpose	Telecom	General P	urpose	High Per- formance	Telecom		
Part Numb	er (G3VM-)		-61B1	-XN	-351B	-3L	-353B	-401B	-4N	-401BY	-601BY	
Output	Load Voltage		60 V	60 V	350 V	350 V	350 V	400 V	400 V	400 V	600 V	
	Function		1a	1a hiperf	1a	1a CLF	1b	1a	1a hiperf	1a hi isol	1a hi isol	
	Cont. load curr (connection A)	rent	500 mA	300 mA	120 mA	120 mA	150 mA	120 mA	150 mA	120 mA	100 mA	
	ON resistance	Typical	1 Ω	1.4 Ω	25 Ω	22 Ω	15 Ω	17 Ω	-	17 Ω	25 Ω	
		Max.	2 Ω	2 Ω	35 Ω	35 Ω	25 Ω	35 Ω	12 Ω	35 Ω	35 Ω	
Input	LED forward co	urrent	50 mA	mA 30 mA 50 mA 30 mA 50 mA						mA		
	LED reverse vo (max)	oltage		5 V								
	Trigger LED	Typical	1.6 mA	1 mA	1 mA	-	1 mA	1 mA	1 mA	_	1.6 mA	
	current	Max.	3 mA	5 mA	3 mA	3 mA	3 mA	3 mA	5 mA	3 mA	5 mA	
Switching	Turn-on Time	Typical	0.8 ms	0.2 ms	0.3 ms	-	0.1 ms	0.3 ms	0.3 ms	0.3 ms	0.2 ms	
Charact- eristics		Max.	2 ms	0.5 ms	1 ms	1 ms	1 ms	1 ms	1 ms	1 ms	1.5 ms	
	Turn-off Time	Typical	0.1 ms	0.2 ms	0.1 ms	-	1 ms	0.1 ms	0.3 ms	0.1 ms	0.2 ms	
		Max.	0.5 ms	0.5 ms	1 ms	1 ms	3 ms	1 ms	1 ms	1 ms	1 ms	
Dielectric \$ I/O termina	Strength betwee	n				2,500 VAC	;			5,000	VAC	
Tempera-	Operating						40°C to 85°	С				
ture	Storage					-5	55°C to 125°	,C				
Floating ca	pacity between						0.8 pF					
Insulation	resistance						1,000 ΜΩ					
Page			380	382	385	387	389	391	393	396	398	



Style			Small O	utline Pa	ckage – 6	pin		Through	-hole De	vice – 8 p	oin		
		4	d	THE THE PERSON NAMED IN COLUMN TWO IS NOT THE PERSON NAMED IN COLUMN TO THE PERSON NAMED IN COLU									
Dimension	s (L x W x H mm	1)	7.0 x 6.3	3 x 2.1				7.62 x 9	66 x 3.65	i			
Туре			General	Purpose				General	Purpose	Telecom	General	Purpose	
Part Numb	er (G3VM-)		-61H1	-201H1	-351H	-353H	-401H	-62C1	-352C	-WL	-354C	-355C	-402C
Output	Load Voltage		60 V	200 V	350 V	350 V	400 V	60 V	350 V	350 V	350 V	350 V	400 V
	Function		1a	1a	1a	1b	1a	2a	2a	2a CLF	2b	1c	2a
	Cont. load curr (connection A)	ent	400 mA	200 mA	110 mA	120 mA	120 mA	500 mA	120 mA	120 mA	150 mA	100 mA	120 mA
	ON resistance	Typical	1 Ω	5 Ω	25 Ω	15 Ω	17 Ω	1 Ω	25 Ω	22 Ω	15 Ω	30 Ω	18 Ω
		Max.	2 Ω	8 Ω	35 Ω	25 Ω	35 Ω	2 Ω	50 Ω	35 Ω	25 Ω	35 Ω	35 Ω
Input	LED forward co	urrent	50 mA				50 mA						
	LED reverse vo (max)	oltage	5 V				5	5 V 6 V 5 V					
	Trigger LED	Typical	1.6 mA	1 mA	1 mA	1 mA	1 mA	1.6 mA	1 mA	1 mA	1 mA	1 mA	1 mA
	current	Max.	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA
Switching Charact-	Turn-on Time	Typical	0.8 ms	0.6 ms	0.3 ms	-	0.3 ms	0.8 ms	0.3 ms	-	0.1 ms	0.3 ms	-
eristics		Max.	2 ms	1.5 ms	1 ms	1 ms	1 ms	2 ms	1 ms	1 ms	1 ms	1 ms	1 ms
	Turn-off Time	Typical	0.1 ms	0.1 ms	0.1 ms	-	0.1 ms	0.1 ms	0.1 ms	-	1 ms	0.15 ms	-
		Max.	0.5 ms	1 ms	1 ms	3 ms	1 ms	0.5 ms	1 ms	1 ms	3 ms	1 ms	1 ms
Dielectric S I/O termina	Strength betwee	n			1,500 VAC					2,500) VAC		
Tempera-	Operating			-4	0°C to 85	°C				-40°C	to 85°C		
ture	Storage			-5	5°C to 12	5°C				-55°C t	o 125°C		
Floating ca	pacity between als				0.8 pF					0.8	3 pF		
Insulation	resistance				1,000 MΩ	2				1,00	0 ΜΩ		
Page			400	402	404	406	408	410	412	414	416	418	420

Surface Mount Device - 8 pin

7.62 x 9.66 x 3.65

-352F

350 V

2a

50 Ω

1.6 mA 1 mA

0.8 ms | 0.3 ms

0.1 ms | 0.1 ms

0.5 ms | 1 ms

3 mA 3 mA

2 ms

410 412 Tele-

com

-WFL

350 V 350 V

22 Ω 15 Ω

 35Ω 25 W

6 V 5 V

1 mA

1 ms 1 ms

1 ms 3 ms

2a CLF 2b

500mA | 120mA | 120mA | 150mA | 100mA | 120mA

50 mA

1 mA

3 mA

0.1 ms

1 ms

2.500 VAC

-40°C to 85°C

-55°C to 125°C

0.8 pF

1.000 MΩ

416

414

General Purpose

-355F

350 V

1c 2a

30 Ω

 35Ω 35 Ω

1 mA 1 mA

3 mA

0.3 ms

1 ms

0.15 ms

1 ms

418

420

-402F

400 V

18 Ω

3 mA

1 ms

-354F

General

-62F1

60 V

2a

1 Ω

2Ω

Style

Type

Output

Input

Switching

Charact-

eristics

I/O terminals

I/O terminals

Page

Tempera-

Dimensions (L x W x H mm)

Part Number (G3VM-)

Load Voltage

Cont. load current

ON resistance Typical

LED forward current

LED reverse voltage

Max.

Typical

Max.

Typical

Typical

Max.

(connection A)

Function

(max)

(max) Trigger LED

current

Dielectric Strength between

Operating

Storage

Floating capacity between

Insulation resistance

Turn-on Time

Turn-off Time

Small Outline Package - 8 pin

7 x 9.4 x 2.1

-62J1

60 V

2a

1Ω

2Ω

3 mA

2 ms

422

424

General Purpose

-202J1 -352J

350 V

400mA 200mA 110mA 120mA 90mA

35 Ω

1 mA 1 mA

3 mA

0.3 ms

1 ms 1 ms

0.1 ms

1 ms 3 ms

1.500 VAC

-40°C to 85°C

-55°C to 125°C

0.8 pF

1.000 MΩ

426 428

50 Ω 25 Ω

50 mA

5 V

2a

200 V

2a

5Ω

8Ω

1.6 mA 1 mA

0.8 ms | 0.6 ms

0.1 ms | 0.1 ms

0.5 ms | 1 ms

3 mA

1.5 ms

-354J

350 V

2b

15 Ω

-355J -402J

350 V

1c

30 Ω

35 Ω

1 mA

3 mA

1 ms

1 ms

430

400 V

17 Ω

35 Ω

1 mA

3 mA

ms

1 ms

0.3 ms | 0.3 ms

0.15ms 0.1 ms

OMROF

Compact, General-purpose, Analog switching MOSFET Relay, with Dielectric Strength of 2.5 kVAC between I/O Using Optical Isolation

- Upgraded G3VM-61 A/D Series.
- Switches minute analog signals.
- Leakage current of 1 A max. when output relay is open.



Note: The actual product is marked differently from the image

■Application Examples

- · Measurement devices
- · Security systems
- · Amusement machines

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	als 60 VAC G3VM-61A1		100	
	Surface-mounting		G3VM-61D1		
	terminals		G3VM-61D1(TR)		1,500

■ Dimensions

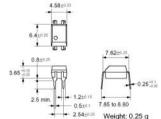
Note: All units are in millimeters unless otherwise indicated



G3VM-61A1





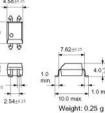




G3VM-61D1

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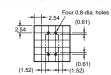
■Terminal Arrangement/Internal Connections (Top View)

G3VM-61A1



■PCB Dimensions (Bottom View)

G3VM-61A1



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-61D1



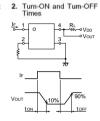
357

	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA.	
	Repetitive peak LED forward current	Ipp	1	A	100 μs pulses, 100 pps
	LED forward current reduc- tion rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	٧	
	Connection temperature	Ti	125	°C	
Output	Output dielectric strength	V _{OFF}	60	V	-
	Continuous load current	lo	500	mA	
	ON current reduction rate	∆ l _{ON} PC	-5.0	mA/°C	Ta ≥ 25°C
	Connection temperature	T _j	125	°C	
Dielectric strength between input and output (See note 1.)		V _{I-O}	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Solderin	g temperature (10 s)		260	°C	10 s

The dielectric strength between the input and output was checked by applying voltage be-tween all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	٧	I _F = 10 mA
	Reverse current	I _R			10	μА	V _R = 5 V
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	I _{FT}		1.6	3	mA	I _O = 500 mA
Output	Maximum resistance with output ON	RON	-	1	2	Ω	I _F = 5 mA, I _O = 500 mA
	Current leakage when the relay is open	ILEAK			1.0	μA	V _{OFF} = 60 V
Capacity	y between I/O terminals	CI-O		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000	-		MΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON		0.8	2.0	ms	I _F = 5 mA, R _L = 200 Ω,
Tum-OF	Turn-OFF time		***	0.1	0.5	ms	V _{DD} = 20 V (See note 2



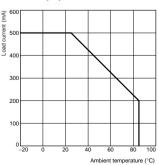
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			48	V
Operating LED forward current	I _E	5	7.5	25	mA
Continuous load current	lo		-	500	mA
Operating temperature	Ta	- 20	-	65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-61A1(D1)



Analog-switching MOSFET Relays with 350-V Load Voltage and **Current Limit.**

- A 4-pin Relay available with the same terminal-pin position as 4-pin photocouplers.
- Approved standards: UL1577 (File No. E80555)

■Application Examples

- · Electronic automatic exchange systems
- · Cordless telephones
- · Multi-functional telephones
- · Measurement devices



Note: The actual product is marked differently from the image

■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Current limit	Number per stick	Number per tape
SPST-NO	PCB terminals	350 VAC	G3VM-2L	Yes	100	
	Surface-mounting		G3VM-2FL			
	terminals		G3VM-2FL(TR)	Ī		1,500

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



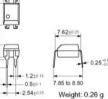


Note: The actual product

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■ Terminal Arrangement/Internal Connections (Top View)

G3VM-2L



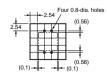
G3VM-2FL

360



■PCB Dimensions (Bottom View)

G3VM-2L



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-2FL



	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	1 _F	50	mA	
	Repetitive peak LED forward current	lp	1	Α	100 μs pulses, 100 pps
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	6	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	VOFF	350	V	
	Continuous load current	I _O	120	mA	
	ON current reduction rate	ΔI _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C
	Connection temperature	Tį	125	°C	
	ic strength between input and See note 1.)	V _{FO}	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	"C	With no icing or condensation
Soldering temperature (10 s)			260	*C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R			10	μА	V _R = 6 V
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	IFT	***	1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	R _{ON}	No.	22	35	Ω	I _F = 5 mA, I _O = 120 mA
	Current leakage when the relay is open	LEAK	775	-	1.0	μА	V _{OFF} = 350 V
Limit cu	rrent	ILM	150	-	300	mA	I _F = 5 mA, V _{DD} = 5 V. t = 5 ms
Capacity	y between I/O terminals	C _{1-O}	***	0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000			МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time Turn-OFF time		tON		-	1.0	ms	I _F = 5 mA, R _L = 200 Ω,
		tOFF		-	1.0	ms	V _{DD} = 20 V (See note 2.

2. Turn-ON and Turn-OFF Times 1 0 4 Load 3 AC/DC 0 1 5 1 0 4 Rt. Voor Wourt 10 10% 10% 10FF

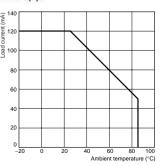
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V.
Operating LED forward current	1 _F	5	7.5	25	mA
Continuous load current	l _O	_		100	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-2(F)L



New Standard Series with 350-V Load

- Upgraded G3VM-2 Series.
- Continuous load current of 120 mA.
- Dielectric strength of 2,500 Vrms between I/O.
- Operating time of 0.3 ms (typical)



■Application Examples

- Measurement devices
- · Security systems
- · Amusement machines

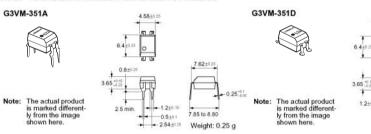
Note: The actual product is marked differently from the image shown here.

■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	350 VAC	G3VM-351A	100	
	Surface-mounting		G3VM-351D		
	terminals		G3VM-351D(TR)		1,500

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



■ Terminal Arrangement/Internal Connections (Top View)





G3VM-351D

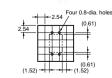


2.54+0.25

Weight: 0.25 g

■PCB Dimensions (Bottom View)

G3VM-351A



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-351D



	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	1 _F	50	mA	
	Repetitive peak LED forward current	I _{FP}	1	A	100 µs pulses, 100 pps
	LED forward current reduction rate	Δ I _F I°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	Ti	125	°C	
Output	Output dielectric strength	V _{OFF}	350	V	in the second
	Continuous load current	I ₀	120	mA	
	ON current reduction rate	A lon ™C	-1.2	mA/°C	Ta ≥ 25°C
	Connection temperature	Ti	125	°C	
Dielectr output (ic strength between input and See note 1.)	VIO	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R	-		10	μА	V _R = 5 V
	Capacity between terminals	CT	-	30	1773	pF	V = 0, f = 1 MHz
	Trigger LED forward current	IFT		1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	R _{ON}		25	35	Ω	I _F = 5 mA, I _O = 120 mA, t < 1 s
			-	35	50	Ω	I _F = 5 mA, I _O = 120 mA
	Current leakage when the relay is open	I _{LEAK}			1.0	μА	V _{OFF} = 350 V
Capacity	y between I/O terminals	CIO		0.8		pF	f = 1 MHz, Vs = 0 V
Insulatio	on resistance	R _{FO}	1,000			МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON		0.3	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Turn-OF	Turn-OFF time			0.1	1.0	ms	V _{DD} = 20 V (See note 2.)

2. Turn-ON and Turn-OFF

■ Recommended Operating Conditions

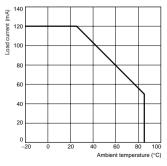
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V ₀₀		-	280	V
Operating LED forward current	1 _F	5	7.5	25	mA
Continuous load current	lo lo			100	mA
Operating temperature	Ta	- 20	-	65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-351A(D)



Analog-switching MOSFET Relay with SPST-NC (Single-pole, Singlethrow. Normally Closed) Contacts

- Switches minute analog signals.
- Switching AC and DC.

■Application Examples

- · Electronic automatic exchange systems
- · Security systems
- · Datacom (modem) systems
- · FA systems
- · Measurement devices



The actual product is marked differently from the image shown here.

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NC	PCB terminals	350 VAC	G3VM-353A	100	
	Surface-mounting		G3VM-353D		
	terminals		G3VM-353D(TR)		1,500

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-353A

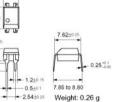


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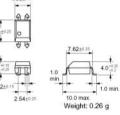
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■ Terminal Arrangement/Internal Connections (Top View)

G3VM-353A

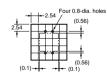






■PCB Dimensions (Bottom View)

G3VM-353A



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-353D

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G3VM-353D

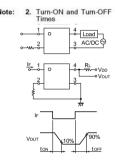


Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	1 _F	50	mA	
	Repetitive peak LED forward current	IFP	1	A	100 μs pulses, 100 pps
	LED forward current reduction rate	Δ1 _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	V_R	5	V	
	Connection temperature	Tj	125	"C	
Output	Output dielectric strength	V _{OFF}	350	V	
	Continuous load current	I _O	150	mA	
	ON current reduction rate	∆ l _{ON} /°C	-1.5	mA/°C	Ta ≥ 25°C
	Connection temperature	T _j	125	°C	
Dielectr output (ic strength between input and See note 1.)	V _{FO}	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	"C	With no icing or condensation
Soldering temperature (10 s)		_	260	°C	10 s

te: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R			10	μА	V _R = 5 V
	Capacity between termi- nals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward cur- rent	1 _{FT}		1	3	mA	I _{OFF} = 10 μA
Output	Maximum resistance with output ON	R _{ON}		15	25	Ω	I _O = 150 mA
	Current leakage when the relay is open	I _{LEAK}			1.0	μΑ	I _F = 5 mA, V _{OFF} = 350 V
Capacit	y between I/O terminals	CI-O		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000		-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time Turn-OFF time		tON		0.1	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
		tOFF		1.0	3.0	ms	V _{DD} = 20 V (See note 2.)



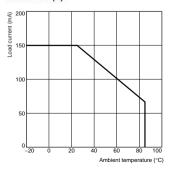
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}		-	280	V
Operating LED forward current	I _F	5		25	mA
Continuous load current	l _o			150	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-353A(D)



Expanded Range of Analogswitching MOSFET Relays with 400-V Load Voltage

- A 4-pin Relay now available in the 400-V load voltage series.
- Continuous load current of 120 mA.
- Dielectric strength of 2,500 Vrms between I/O.



NEW Approval pending

■Application Examples

- · Measurement devices
- · Security systems
- · Amusement machines

Note: The actual product is marked differently from the image shown here.

■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	400 VAC	G3VM-401A	100	
	Surface-mounting		G3VM-401D		z.
	terminals		G3VM-401D(TR)		1,500

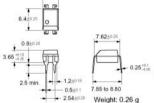
■ Dimensions

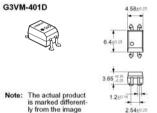
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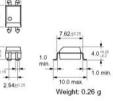
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Note: All units are in millimeters unless otherwise indicated.









■ Terminal Arrangement/Internal Connections (Top View)

G3VM-401A

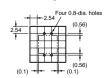


G3VM-401D



■PCB Dimensions (Bottom View)

G3VM-401A



■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-401D

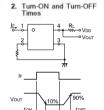


	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	IFP	1	Α	100 µs pulses, 100 pps
	LED forward current reduction rate	Δ1 _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	V _{OFF}	400	V	
	Continuous load current	lo.	120	mA	
	ON current reduction rate	∆ I _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C
	Connection temperature	T _j	125	°C	
Dielectr output (ic strength between input and See note 1.)	VIIO	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)		***	260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R			10	μА	V _R = 5 V
	Capacity between terminals	CT		30	-	pF	V = 0, f = 1 MHz
	Trigger LED forward current	I _{FT}	***	1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	RON		18	35	Ω	I _F = 5 mA, I _O = 120 mA
	Current leakage when the relay is open	LEAK			1.0	μА	V _{OFF} = 400 V
Capacit	y between I/O terminals	CHO	***	0.8	-	pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000		-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON	***		1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Turn-OFF time		tOFF			1.0	ms	V _{DD} = 20 V (See note 2.)



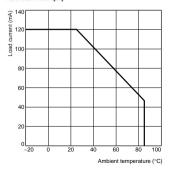
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}		-	320	V
Operating LED forward current	l _F	5	7.5	25	mA
Continuous load current	lo			100	mA
Operating temperature	T _a	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-401A(D)



New MOSFET Relay Designed for Switching Minute Signals and Analog Signals

MOSFET Relay - G3VM-61G1

- Upgraded G3VM-S1 Series.
- Continuous load current of 400 mA.
- Dielectric strength of 1,500 Vrms between I/O.





■Application Examples

- · Broadband systems
- · Data loggers
- · Measurement devices
- · Amusement machines

■List of Models

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Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	60 VAC	G3VM-61G1	100	
ı	terminals		G3VM-61G1(TR)	***	2,500

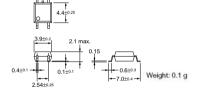
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.





Note: The actual product is marked differently from the image shown here.



■Terminal Arrangement/Internal Connections (Top View)

G3VM-61G1



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-61G1



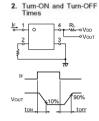
Item		Symbol	Rating	Unit	Measurement Conditions	
Input	LED forward current	I _F	50	mA		
	Repetitive peak LED forward current	IFP	1	Α	100 μs pulses, 100 pps	
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C	
	LED reverse voltage	V _R	5	V		
	Connection temperature	T _i	125	°C		
Output	Output dielectric strength	V _{OFF}	60	V		
	Continuous load current	lo .	400	mA		
	ON current reduction rate	∆ l _{ON} /°C	-4.0	mA/°C	Ta ≥ 25°C	
	Connection temperature	T _i	125	÷C		
Dielectric strength between input and output (See note 1.)		VIO	1,500	Vrms	AC for 1 min	
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation	
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation	
Soldering temperature (10 s)			260	°C	10 s	

Note:

1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R		-	10	μА	V _R = 5 V
	Capacity between terminals	CT	2005	30	-	pF	V = 0, f = 1 MHz
	Trigger LED forward current	IFT		1.6	3	mA	I _O = 400 mA
Output	Maximum resistance with output ON	R _{ON}		1	2	Ω	I _F = 5 mA, I _O = 400 mA
	Current leakage when the relay is open	LEAK	-	-	1.0	μА	V _{OFF} = 60 V
Capacity	y between I/O terminals	CIO	350	0.8	-	pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000	-	-	МΩ	V _{I.O} = 500 VDC, RoH ≤ 60%
Turn-ON time Turn-OFF time		ION	***	0.8	2.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
		tOFF	***	0.1	0.5	ms	V _{DD} = 20 V (See note 2



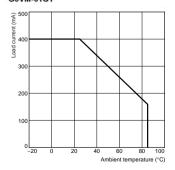
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}	-	-	48	V
Operating LED forward current	l _F	5	7.5	25	mA
Continuous load current	lo			400	mA
Operating temperature	Ta	- 20		65	°C

■Engineering Data

Load Current vs. Ambient Temperature G3VM-61G1



New Relay Incorporating a MOSFET Optically Coupled with an Infrared LED

MOSFET Relay - G3VM-81G1

Has a 4-pin SOP Package and 80-V Load Voltage

- Continuous load current of 350 mA.
- Dielectric strength of 1,500 Vrms between I/O.

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Note: The actual product is marked differently from the image

NEW 91

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- Amusement machines

■ List of Models

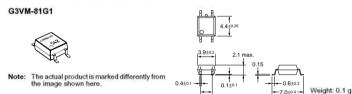
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Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	80 VAC	G3VM-81G1	100	
	terminals		G3VM-81G1(TR)		2,500

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



■ Terminal Arrangement/Internal Connections (Top View)





■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-81G1



	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	Ipp	1	А	100 μs pulses, 100 pps
	LED forward current reduction rate	Δ I _F PC	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	V _R	5	٧	
	Connection temperature	T _j	125	°C.	
Output	Output dielectric strength	V _{OFF}	80	V	
	Continuous load current	I ₀	350	mΑ	
	ON current reduction rate	∆ lon/°C	-3.5	mA/°C	Ta ≥ 25°C
	Connection temperature	T _i	125	°C	
	ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min
Operati	ng temperature	Ta	-40 to +85	°C	With no icing or condensation
Storage	temperature	T _{stg}	-55 to +125	°C	With no icing or condensation
Solderin	ng temperature (10 s)		260	°C	10 s

Note:

1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

	Item	Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	IR		-	10	μА	V _R = 5 V
	Capacity between terminals	CT		15		pF	V = 0, f = 1 MHz
	Trigger LED forward current	l _{FT}		1.0	4.0	mA	I _O = 350 mA
Output	Maximum resistance with output ON	RON		1.0	1.2	Ω	I _F = 5 mA, I _O = 350 mA
	Current leakage when the relay is open	LEAK		0.2	1.0	nA	V _{OFF} = 30 V, Ta = 50°C
Capacit	y between I/O terminals	CIO		0.8		pF	f = 1 MHz, Vs = 0 V
Insulatio	on resistance	R _{I-O}	1,000			МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON	220	0.3	0.5	ms	I _F = 5 mA, R _L = 200 Ω,
Turn-OF	Turn-OFF time			0.3	0.5	ms	V _{DD} = 20 V (See note 2.)

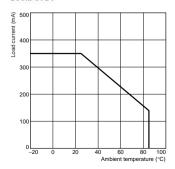
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Symbol	Minimum	Typical	Maximum	Unit
V _{DD}			64	V
l _F	5		30	mA
lo	_	-	350	mA
Ta	25	-	60	°C
	-	V _{DD} I _F 5 I _O	V _{DD} I _F 5	V _{DD} 84 I _F 5 30 I _O 350

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-81G1



Slim, 2.1-mm High MOSFET Relay with Miniature, Flat, 4-pin SOP Package Load Voltage

MOSFET Relay - G3VM-201G

- New models with 4-pin SOP package now available in the 200-V load voltage series.
- Leakage current of 0.01µA max. when output relay is open.
- Dielectric strength of 1,500 Vrms between I/O.

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shown here.

■ Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- · Amusement machines

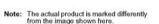
■List of Models

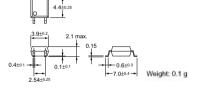
Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	200 VAC	G3VM-201G	100	***
	terminals		G3VM-201G(TR)		2,500

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.







■ Terminal Arrangement/Internal Connections (Top View)

G3VM-201G



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-201G



	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	lF	50	mA	
	Repetitive peak LED forward current	IFP	1	A	100 μs pulses, 100 pps
	LED forward current reduction rate	ΔIpPC	-0.5	mA/°C	Ta≥25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	VOFF	200	V	
	Continuous load current	lo	50	mA	
	ON current reduction rate	∆ I _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C
	Connection temperature	Tj	125	°C	
	ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min
Operati	ng temperature	Ta	-40 to +85	°C	With no icing or condensation
Storage	temperature	T _{stg}	-55 to +100	°C	With no icing or condensation
Solderin	ng temperature (10 s)		260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

	Item	Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R			10	μА	V _R = 5 V
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	1 _{FT}		1	3	mA	I _O = 50 mA
Output	Maximum resistance with output ON	R _{CN}	-	30	50	Ω	I _F = 5 mA, I _O = 50 mA
	Current leakage when the relay is open	LEAK			0.01	μА	V _{OFF} = 200 V, Ta = 25°C
Capacity	y between I/O terminals	CHO		0.8	-	pF	f = 1 MHz, Vs = 0 V
Insulatio	on resistance	R _{I-O}	1,000		-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Tum-ON	N time	tON		0.04	0.1	ms	I _F = 10 mA, R _L = 200 Ω,
Tum-OF	F time	tOFF	***	0.1	0.2	ms	V _{DD} = 10 V (See note 2.)

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Note: 2. Turn-ON and Turn-OFF

■ Recommended Operating Conditions

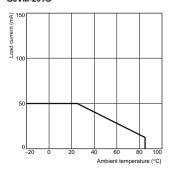
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			160	V
Operating LED forward current	I _F	5	7.5	15	mA
Continuous load current	lo			40	mA.
Operating temperature	Ta	25		60	°C

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■ Engineering Data

Load Current vs. Ambient Temperature G3VM-201G



Slim, 2.1-mm High Relay Incorporating a MOSFET Optically Coupled with an Infrared LED in a Miniature, Flat SOP

- Upgraded G3VM-S2 Series.
- Continuous load current of 110 mA.
- Dielectric strength of 1,500 Vrms between I/O.



Note: The actual product is marked differently from the image

■ Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- · Amusement machines

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	350 VAC	G3VM-351G	100	
9	terminals		G3VM-351G(TR)		2,500

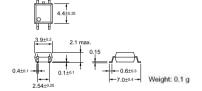
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-351G



Note: The actual product is marked differently from the image shown here.



■ Terminal Arrangement/Internal Connections (Top View)

G3VM-351G



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-351G



	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	IFP	1	A	100 µs pulses, 100 pps
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	V _R	5	V	8
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	VOFF	350	V	
	Continuous load current	l ₀	110	mA	
	ON current reduction rate	∆ l _{ON} /°C	-1.1	mA/°C	Ta≥25°C
	Connection temperature	Tj	125	°C	
Dielectr output (ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min
Operati	ng temperature	Ta	-40 to +85	°C	With no icing or condensation
Storage	temperature	T _{stg}	-55 to +125	°C	With no icing or condensation
Solderin	ng temperature (10 s)		260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

	Item	Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R			10	μА	V _R = 5 V
	Capacity between terminals	CT	 3	30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	1 _{FT}		1:	3	mA	I _O = 100 mA
Output	Maximum resistance with output ON	R _{ON}		25	35	Ω	I _F = 5 mA, I _O = 110 mA, t < 1 s
				35	50	Ω	I _F = 5 mA, I _O = 110 mA
	Current leakage when the relay is open	ILEAK	_	-	1.0	μА	V _{OFF} = 350 V
Capacity	y between I/O terminals	CI-O	220	0.8	-	pF	f = 1 MHz, Vs = 0 V
Insulatio	on resistance	R _{I-O}	1,000		-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Tum-ON	N time	tON	·	0.3	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Tum-OF	F time	tOFF		0.1	1.0	ms	V _{DD} = 20 V (See note 2.)

2. Tum-ON and Turn-OFF

■ Recommended Operating Conditions

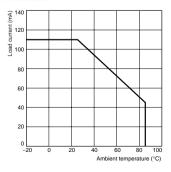
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	1 _F	5	7.5	25	mA
Continuous load current	l _O			100	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-351G



Analog-switching MOSFET Relay with SPST-NC (Single-pole, Single-throw, Normally Closed) Contacts

- New models with SPST-NC contacts and a 4-pin SOP package included in 350-V load voltage series.
- Continuous load current of 120 mA.
- Dielectric strength of 1,500 Vrms between I/O.



Note: The actual product is marked differently from the image shown here.

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- · Amusement machines

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NC	Surface-mounting	350 VAC	G3VM-353G	100	575
	terminals		G3VM-353G(TR)		2,500

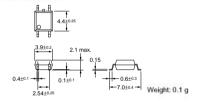
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-353G



Note: The actual product is marked differently from the image shown here.



■Terminal Arrangement/Internal Connections (Top View)

G3VM-353G



■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-353G



OMROF

■ Absolute Maximum Ratings (Ta = 25°C)

	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	I _F	50	mA	
	Repetitive peak LED forward current	I _{FP}	1	А	100 μs pulses, 100 pps
į.	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	VOFF	350	V	
	Continuous load current	lo	120	mA	
1	ON current reduction rate	∆ l _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C
	ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R	***		10	μА	V _R = 5 V
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	IFT		1	3	mA	I _{OFF} = 10 μA
Output	Maximum resistance with output ON	RON		15	25	Ω	I _O = 120 mA
	Current leakage when the relay is open	LEAK			1.0	μА	V _{OFF} = 350 V, I _F = 5 mA
Capacity	y between I/O terminals	CI-O		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000	-	-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON	ann .	***	1.0	ms	$I_F = 5 \text{ mA}$, $R_L = 200 \Omega$,
Turn-OFF time		tOFF			3.0	ms	V _{DD} = 20 V (See note 2.)

■ Recommended Operating Conditions

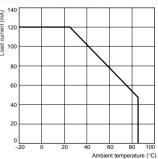
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}	-		280	V
Operating LED forward current	1 _E	5		25	mA
Continuous load current	lo .			120	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-353G



Expanded Range of Analog-Switching MOSFET Relays in 400-V Load Voltage Series

- New models with a 4-pin SOP package now included in the 400-V load voltage series.
- Continuous load current of 120 mA.
- Dielectric strength of 1,500 Vrms between I/O.



The actual product is marked differently from the image

shown here.

NEW **91**

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- Amusement machines

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	400 VAC	G3VM-401G	100	
	terminals		G3VM-401G(TR)		2,500

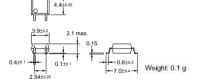
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-401G



Note: The actual product is marked differently from the image shown here.



■ Terminal Arrangement/Internal Connections (Top View)

G3VM-401G



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-401G



Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	1 _F	50	mA	
	Repetitive peak LED forward current	Ipp	1	A	100 μs pulses, 100 pps
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	V _R	5	V	
	Connection temperature	T _i	125	°C	
Output	Output dielectric strength	V _{OFF}	400	V	
	Continuous load current	lo	120	mA	
	ON current reduction rate	∆ I _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C
Dielectr output (ic strength between input and See note 1.)	VI-O	1,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R	-	-	10	μА	V _R = 5 V
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	I _{FT}		1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	Ron	-	17	35	Ω	I _F = 5 mA, I _O = 120 mA
	Current leakage when the relay is open	ILEAK		-	1.0	μА	V _{OFF} = 400 V
Capacity	y between I/O terminals	CI-O	-	0.8	-	pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000			МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON		0.3	1	ms	I_F = 5 mA, R_L = 200 $Ω$,
Turn-OFF time		tOFF		0.1	1	ms	V _{DD} = 20 V (See note 2.

2. Turn-ON and Turn-OFF

■ Recommended Operating Conditions

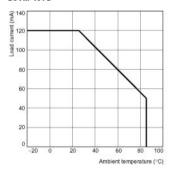
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}	-	-	320	٧
Operating LED forward current	1 _F	5	7.5	25	mA
Continuous load current	lo			120	mA
Operating temperature	Ta	- 20	-	65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-401G



Analog-Switching MOSFET Relay for High Switching Currents, with Dielectric Strenath of 2.5 kVAC between I/O.

- Upgraded G3VM-61 B/E Series.
- Switches minute analog signals.
- Leakage current of 1µA max. when output relay is open.





■Application Examples

- · Measurement devices
- · Security systems
- · Amusement machines

Note: The actual product is marked differently from the image shown here.

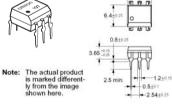
■ List of Models

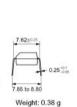
Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	60 VAC	G3VM-61B1	50	
	Surface-mounting	7	G3VM-61E1		
	terminals		G3VM-61E1(TR)		1,500

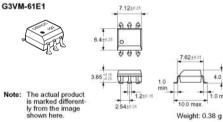
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.









■ Terminal Arrangement/Internal Connections (Top View)

G3VM-61B1

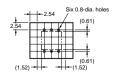


G3VM-61E1



■PCB Dimensions (Bottom View)

G3VM-61B1



■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-61E1



			Symbol	Rating	Unit	Measurement Conditions
Input	nput LED forward current		l _F	50	mA	
	Repetitive per current	ak LED forward	l _{EP}	1	А	100 μs pulses, 100 pps
	LED forward o	urrent reduction	ΔI _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse	voltage	VR	5	V	
	Connection te	emperature	T _i	125	°C	
Output	Output dielectric strength		VoFF	60	V	
	Continuous load current	Connection A	lo	500	mA	
		Connection B		500		
		Connection C		1,000		
	ON current	Connection A	∆ l _{ON} /°C	-0.5	mA/°C	Ta ≥ 25°C
	reduction rate	Connection B		-0.5		
	1770	Connection C	1	-10.0		
	Connection to	emperature	Tj	125	°C	
Dielectric strength between input and output (See note 1.)		V _{I-O}	2,500	Vrms	AC for 1 min	
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation	
Storage	temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)				260	°C	10 s

Note:	1.	The dielectric strength between the input and output was checked by applying voltage be-
		tween all pins as a group on the LED side and all pins as a group on the light-receiving side.

Connection D	nagram
Connection A	1 6 1 Load 1 2 5 0 or AC O
Connection B	2 5 DC 7
Connection C	2 5 DC

■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage		VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current		IR		-	10	μА	V _R = 5 V
	Capacity between terr	ninals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current		IFT		1.6	3	mA	I _O = 500 mA
Output	Maximum resistance with output ON	Connection A	RON		1	2	Ω	I _F = 5 mA, I _O = 500 mA
		Connection B			0.5	1:	Ω	I _F = 5 mA, I _O = 500 mA
		Connection C		-	0.25	50 6	Ω	I _F = 5 mA, I _O = 1,000 mA
	Current leakage when the relay is open		ILEAK		-	1.0	μА	V _{OFF} = 60 V
Capacit	y between I/O terminals	i.	CI-O		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000			МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%	
Turn-ON time		tON	-	0.8	2.0	ms	I_F = 5 mA, R_L = 200 $Ω$,	
Turn-OFF time		tOFF	***	0.1	0.5	ms	V _{DD} = 20 V (See note 2.	

Note: 2. Turn-ON and Turn-OFF

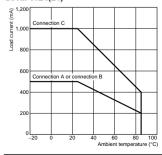
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}	-	Tes	48	V
Operating LED forward current	JE.	5	7.5	25	mA
Continuous load current	lo lo	-		500	mA
Operating temperature	Ta	- 20		65	°C

■Engineering Data

Load Current vs. Ambient Temperature G3VM-61B1(E1)



with an I/O Dielectric Strength of 2.5 kVAC Using Optical Isolation ■ Switches minute analog signals.

MOSFET Relay - G3VM-XN(F)

SSR for Switching Analog Signals,

- Linear voltage and current characteristics.
- Switches AC and DC.
- Low ON-resistance.
- Current leakage less than 1 µA between output terminals when they are open.
- Surface-mounting models also available.
- UL/CSA approval pending.



Ordering Information -

Contact form	Terminals	Load Voltage (peak value)	Model	Number per stick	Taping quantity
SPST-NO	PCB terminals	60 VAC	G3VM-XN	50	-
		400 VAC	G3VM-4N		
	Surface-mounting	60 VAC	G3VM-XNF		
	terminals	400 VAC	G3VM-4NF		

Model Number Legend



1. Lead Voltage

XN: A load voltage of 60 VDC or 60 VAC (peak value)

4N: A load voltage of 400 VDC or 400 VAC (peak value)

Terminal

None: PCB terminal

Surface mounting terminals

Application Examples -

- · Electronic automatic exchange systems
- · Measurement control systems

- · Data gathering systems
- · Measuring systems

Specifications -

■ Absolute Maximum Ratings (Ta = 25°C)

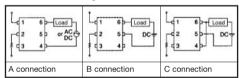
	Item		Symbol	G3VM-XN(F)	G3VM-4N(F)	Conditions
Input	LED forward cu	rrent	I _F	30 mA		-
	Repetitive peak	LED forward current	I _{FP}	1 A		100-µs pulses, 100 pps
	LED reverse vol	tage	V _R	5 V		-
Output		Output dielectric strength		-60 to 60 V	-400 to 400 V	DC or AC peak value
	(load voltage)			0 to 60 V	0 to 400 V	DC
	Continuous load current (see note 1)	A connection	Io	300 mA	150 MA	-
		B connection		450 mA	200 MA	
		C connection		600 mA	300 MA	
Dielectric (see note	strength between 2)	1/0 terminals	V _{I-O}	2,500 V AC		1 min
Ambient	temperature		Та	-20 to 85°C		With no icing or condensation
Storage t	Storage temperature			-55 to 100°C		With no icing or condensation
Max. solo	dering temperature	and time	-	260°C		10 s

Note: 1. The load current attenuation rates for the different types of connection are as follows: G3VM-XN(F): A: -3.0 mA/°C; B: -4.5 mA/°C; C: -6.0 mA/°C

G3VM-4N(F): A: -1.5 mA/°C; B: -2.0 mA/°C; C: -3.0 mA/°C

The dielectric strength between I/O terminals was measured with voltage applied to all of the LED pins and with voltage applied to all of the light-receiving parts respectively.

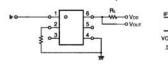
Connection Circuit Diagram



■ Electrical Performance (Ta = 25°C)

	Item		Symbol	G3VM-XN(F)	G3VM-4N(F)	Unit	Conditions
Input	LED forward co	urrent	V _F	1.2 V min, 1.7 V max.		٧	I _F = 10 mA
	Trigger LED forward current		I _{FT}	5 mA max.			$I_{O} = 300 \text{ mA (G3VM-XN(F))}$ $I_{O} = 150 \text{ mA (G3VM-4N(F))}$
Output ON A Connection		R _{ON}	2 Ω max.	12 Ω max.	Ω	I _F = 10 mA	
	resistance	B Connection		1 Ω max.	6 Ω max.		I _O = Max.
		C Connection		0.5 Ω max.	3 Ω max.		
	Switching curr	ent leakage	I _{LEAK}	1.0 μA max.		μА	Voff = 60 V (G3VM-XN(F)) Voff = 400 V (G3VM-4N(F))
Operate t	time		T _{ON}	0.5 ms max.	1.0 ms max.	ms	$R_L = 200 \Omega$ (sse note)
Release t	Release time		T _{OFF}	0.5 ms max. 1.0 ms max.		ms	V _{DD} = 20 V, I _F = 10 mA
Floating	capacity between	I/O terminals	C _{I-O}	0.8 pF, TYP		pF	f = 1MHz

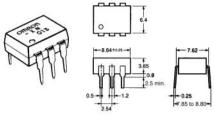
Note: 1. The operate and release time were measured in the way shown below.



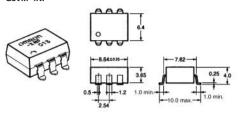
Dimensions -

Note: All units are in millimeters unless otherwise indicated.

G3VM-XN G3VM-4N



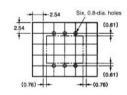
G3VM-XNF G3VM-4NF



Note: "G3VM" is not printed on the actual product.

■ PCB Dimensions (Bottom View)

G3VM-XN G3VM-4N



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-XNF G3VM-4NF



Note: Mounting pad dimensions shown are top view.

Installation

■ Terminal Arrangement/Internal connection (Top View)

G3VM-XN G3VM-4N



G3VM-XNF G3VM-4NF



New Series with 350-V Load Voltage

- Upgraded G3VM-3 Series.
- Continuous load current of 120 mA
- Dielectric strength of 2,500 Vrms between I/O.
- Operating time of 0.3 ms (typical).



Approval pending

Note: The actual product is marked differently from the image shown here.

■Application Examples

- · Measurement devices · Security systems
- · Amusement machines

■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	350 VAC	G3VM-351B	50	
	Surface-mounting	7	G3VM-351E		
	terminals		G3VM-351E(TR)		1,500

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-351B



Note: The actual product is marked different-

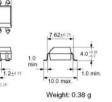




G3VM-351E







■ Terminal Arrangement/Internal Connections (Top View)

G3VM-351B

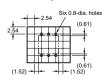


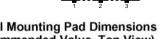
G3VM-351E



■PCB Dimensions (Bottom View)

G3VM-351B





■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

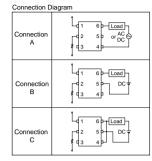
G3VM-351E



■ Absolute Maximum Ratings (Ta = 25°C)

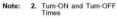
	Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward	current	1 _F	50	mA	
	Repetitive per current	Repetitive peak LED forward current		1	А	100 μs pulses, 100 pps
	LED forward c	urrent reduction	Δ1 _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse v	voltage	VR	5	٧	
	Connection temperature		Tj	125	°C	
Output	Output dielectric strength		V _{OFF}	350	٧	
	Continuous load current	Connection A	lo	120	mA	
		Connection B		120]	
		Connection C	1	240	1	
	ON current	Connection A	∆ lon/°C	-1.2	mA/°C	Ta ≥ 25°C
	reduction rate	Connection B		-1.2		
		Connection C	1	-2.4	1	
	Connection te	emperature	Tj	125	°C	
Dielectr output (ic strength betv See note 1.)	ween input and	V _{I-O}	2,500	Vrms	AC for 1 min
Operati	ng temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage	temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Solderin	ng temperature	(10 s)		260	°C	10 s

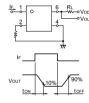
Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.



■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	LED forward voltage		1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current		IR		-	10	μА	V _R = 5 V
	Capacity between term	ninals	CT	-	30		pF	V = 0, f = 1 MHz
	Trigger LED forward current		l _{FT}	-	1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	Connection A	R _{ON}	-	25	35	Ω	I _F = 5 mA, I _O = 120 mA, t < 1 s
					35	50	Ω	I _F = 5 mA, I _O = 120 mA
		Connection B		-	28	40	Ω	I _F = 5 mA, I _O = 120 mA
		Connection C			14	20	Ω	I _F = 5 mA, I _O = 240 mA
	Current leakage when the relay is open		LEAK		-	1.0	μА	V _{OFF} = 350 V
Capacity	between I/O terminals		CHO	-	0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{HO}	1,000	-		МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%	
Turn-ON	l time		tON	#8	0.3	1.0	ms	I _F = 5 mA, R _L = 200 Ω
Turn-OFF time		tOFF	***	0.1	1.0	ms	V _{DD} = 20 V (See note 2	





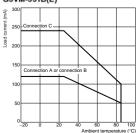
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}		_	280	V
Operating LED forward current	l _F	5	10	25	mA.
Continuous load current	I _O	1	-	100	mA
Operating temperature	Ta	- 20	-	65	*C

■Engineering Data

Load Current vs. Ambient Temperature G3VM-351B(E)



Analog-switching MOSFET Relay with 350-V Load Voltage and **Current Limit.**

■ Approved standards: UL1577 (File No. E80555)

■ Application Examples

- · Electronic automatic exchange systems
- · Multi-functional telephones
- · Cordless telephones
- · Measuring devices



The actual product is marked differently from the image shown here.

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Current limit	Number per stick	Number per tape
SPST-NO	PCB terminals	350 VAC	G3VM-3L	Yes	50	
	Surface-mounting	7	G3VM-3FL	1		
	terminals		G3VM-3FL(TR)			1,500

■ Dimensions

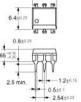
Note: All units are in millimeters unless otherwise indicated.





ly from the image

Note: The actual product is marked different-

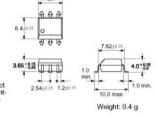




Weight: 0.4 g







■ Terminal Arrangement/Internal Connections (Top View)

G3VM-3L



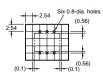
G3VM-3FL

G3VM-3FL



■PCB Dimensions (Bottom View)

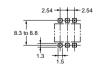
G3VM-3L



■Actual Mounting Pad Dimensions

(Recommended Value, Top View)

G3VM-3FL



■ Absolute Maximum Ratings (Ta = 25°C)

	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	IFP	1	А	100 μs pulses, 100 pps
	LED forward current reduction rate	ΔlpPC	-0.5	mA/°C	Ta≥25°C
	LED reverse voltage	V _R	5	V	
	Connection temperature	T _j	125	°C	
Output	Output dielectric strength	V _{OFF}	350	V	
	Continuous load current	lo .	120	mA	
	ON current reduction rate	∆ l _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C
	Connection temperature	Tj	125	°C	
	ic strength between input and See note 1.)	V _{I-O}	2,500	Vrms	AC for 1 min
Operation	ng temperature	Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Solderin	ng temperature (10 s)		260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

ltem		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	ut LED forward voltage		1.0	1.15	1.3	V	I _F = 10 mA	
	Reverse current	I _R	8775	-	10	μА	V _R = 5 V	
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I _{FT}			3	mA	I _O = 120 mA	
Output	Maximum resistance with output ON	R _{ON}		22	35	Ω	I _F = 5 mA, I _O = 120 mA	
	Current leakage when the relay is open	ILEAK		100	1.0	μΑ	V _{OFF} = 350 V	
Limit cur	rrent	LIM	150		300	mA	I _F = 5 mA, V _{DD} = 5 V, t = 5 ms	
Capacity	y between I/O terminals	CHO		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		Ri-O	1,000	=	-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%	
Turn-ON time		tON		****	1.0	ms	I _F = 5 mA, R _L = 200 Ω,	
Turn-OFF time		tOFF			1.0	ms	V _{DD} = 20 V (See note:	

2. Turn-ON and Turn-OFF Load 4 AC/DC 💝

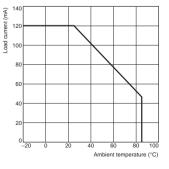
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit	
Output dielectric strength	V _{DD}			280	V	
Operating LED forward current	1 _F	5	7.5	25	mA	
Continuous load current	lo	-	-	120	mA	
Operating temperature	Ta	- 20		65	°C	

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-3(F)L



Analog-switching MOSFET Relay with SPST-NC (Single-pole, Singlethrow. Normally Closed) Contacts

- Switches minute analog signals.
- Switching AC and DC.

■Application Examples

- · Electronic automatic exchange systems
- · Security systems
- · Datacom (modem) systems
- · FA systems
- · Measurement devices





Note: The actual product is marked differently from the image shown here.

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■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NC	PCB terminals	350 VAC	G3VM-353B	50	
	Surface-mounting	1	G3VM-353E	1	
	terminals		G3VM-353E(TR)		1,500

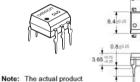
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-353B

is marked different-

ly from the image



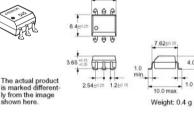








G3VM-353E



■Terminal Arrangement/Internal Connections (Top View)

G3VM-353B

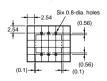


G3VM-353E



■PCB Dimensions (Bottom View)

G3VM-353B





■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-353E



■ Absolute Maximum Ratings (Ta = 25°C)

	Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		l _E	50	mA	
	Repetitive per current	ak LED forward	l _{EP}	1	A	100 μs pulses, 100 pps
	LED forward c	urrent reduction	Δ1 _F /°C	-0.5	mA/°C	Ta≥25°C
	LED reverse	voltage	VR	5	V	
	Connection te	emperature	T _i	125	°C	
Output	Output dielect	tric strength	VoFF	350	V	
	Continuous load current	Connection A	lo	150	mA	
		Connection B		150	1	
		Connection C		300	1	
	ON current	Connection A	∆ l _{ON} /°C	-1.5	mA/°C	Ta ≥ 25°C
	reduction rate	Connection B	1	-1.5		
		Connection C	1	-3.0	1	
	Connection te	emperature	Ti	125	"C	
	ic strength betv See note 1.)	ween input and	V _{I-O}	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation	
Storage	temperature		T _{stg}	-55 to +125	"C	With no icing or condensation
Solderin	ng temperature	(10 s)		260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

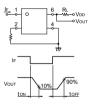
Connection Diagram

Connection D	agram
Connection A	1 6 1 Load 1 0 AC 0 DC
Connection B	1 6 P-Load 1 2 5 P DC
Connection C	1 6 1 Load 1 2 5 DC 1 3 4

■ Electrical Characteristics (Ta = 25°C)

ltem		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage		VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current		I _R	***	***	10	μА	V _R = 5 V
	Capacity between terr	ninals	CT	***	30		pF	V = 0, f = 1 MHz
	Trigger LED forward o	urrent	I _{FT}		1	3	mA	I _{OFF} = 10 μA
Output	Maximum resistance with output ON	Connection A	R _{ON}		15	25	Ω	I _O = 150 mA
		Connection B			8	14	Ω	I _O = 150 mA
		Connection C	1	***	4	7	Ω	I _O = 300 mA
	Current leakage when open	the relay is	LEAK			1.0	μА	I _F = 5 mA, V _{OFF} = 350 \
Capacity	between I/O terminals		CI-O		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000		-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%	
Turn-ON	l time		tON		0.1	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Turn-OF	F time		tOFF		1.0	3.0	ms	V _{DD} = 20 V (See note 2.

Note: 2. Turn-ON and Turn-OFF



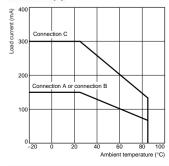
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	J _F	5	-	25	mA
Continuous load current	I _O			150	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-353B(E)



New Series of Analog-switching MOSFET Relays with Dielectric Strength of 2.5 kVAC between I/O **Using Optical Isolation**

- Switches minute analog signals.
- Leakage current of 1µA max. when output relay is open.
- Upgraded G3VM-4N Series.



Note: The actual product is marked differently from the image

■Application Examples

- · Electronic automatic exchange systems
- · Measurement devices
- · FA systems

■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	400 VAC	G3VM-401B	50	
	Surface-mounting		G3VM-401E		
	terminals		G3VM-401E(TR)		1,500

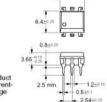
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-401B



The actual product is marked differently from the image



7.85 to 8.80 Weight: 0.38 g



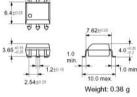




G3VM-401E



shown here.



■Terminal Arrangement/Internal Connections (Top View)

G3VM-401B

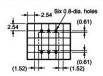


G3VM-401E

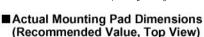


■PCB Dimensions (Bottom View)

G3VM-401B



G3VM-401E



(Recommended Value, Top View)

■ Absolute Maximum Ratings (Ta = 25°C)

Input I ED forward current		Symbol	Rating	Unit	Measurement Conditions	
Input	LED forward current		1 _E	50	mA	
	Repetitive per current	ak LED forward	lpp	1	A	100 μs pulses, 100 pps
	LED forward o	urrent reduction	Δ I _F /°C	-0.5	mA/°C	Ta≥25°C
	LED reverse	voltage	V _R	5	V	
	Connection to	emperature	T _i	125	°C	
Output	Output dielect	tric strength	V _{OFF}	400	V	
	Continuous load current	Connection A	l _O	120	mA	
		Connection B		120	1	
		Connection C		240	1	
	ON current	Connection A	Δ I _{ON} /°C	-1.2	mA/°C	Ta≥25°C
	reduction rate	Connection B		-1.2		
	-	Connection C		-2.4		
	Connection te	emperature	Tj	125	°C	
Dielectr output (ic strength bety See note 1.)	ween input and	V _{I-O}	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation	
Storage	temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Solderin	ng temperature	(10 s)		260	"C	10 s

The dielectric strength between the input and output was checked by applying voltage be-tween all pins as a group on the LED side and all pins as a group on the light-receiving side.

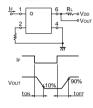
Connection Discussion

Connection L	riagram
Connection A	1 6 b—Load 1 2 5 p or AC 2 5 p or DC
Connection B	1 6 p—Load 1 2 5 p DC 3 4 p
Connection C	2 5 DC

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage		VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current		I _R	553	-	10	μА	V _R = 5 V
	Capacity between term	ninals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward o	urrent	l _{FT}	***	1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	Connection A	R _{ON}	-	17	35	Ω	I _F = 5 mA, I _O = 120 mA
		Connection B			11	20	Ω	I _F = 5 mA, I _O = 120 mA
		Connection C			6	10	Ω	I _F = 5 mA, I _O = 240 mA
	Current leakage when the relay is open		JLEAK	***		1.0	μΑ	V _{OFF} = 350 V
Capacity	between I/O terminals		CI-O	***	0.8	***	pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000	-	-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%	
Turn-ON	l time		tON		0.3	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Turn-OF	Turn-OFF time			222	0.1	1.0	ms	V _{DD} = 20 V (See note 2.

2. Turn-ON and Turn-OFF



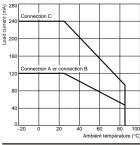
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Symbol Minimum Typ		Maximum	Maximum Unit	
Output dielectric strength	V _{DD}			320	V	
Operating LED forward current	1 _F	5	7.5	25	mA	
Continuous load current	lo)i	120	mA	
Operating temperature	Ta	- 20		65	°C	

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-401B(E)



SSR for Switching Analog Signals, with an I/O Dielectric Strength of 2.5 kVAC Using Optical Isolation

- Switches minute analog signals.
- Linear voltage and current characteristics.
- Switches AC and DC.
- Low ON-resistance.
- Current leakage less than 1 µA between output terminals when they are open.
- Surface-mounting models also available.
- UL/CSA approval pending.



Ordering Information

Contact form	Terminals	Load Voltage (peak value)	Model	Number per stick	Taping quantity
SPST-NO	PCB terminals	60 VAC	G3VM-XN	50	-
	Surface-mounting	400 VAC	G3VM-4N		
		60 VAC	G3VM-XNF		
	terminals	400 VAC	G3VM-4NF		

Model Number Legend



1. Load Voltage

XN: A load voltage of 60 VDC or 60 VAC (peak value)

4N: A load voltage of 400 VDC or 400 VAC (peak value)

2. Terminal

None: PCB terminals

F: Surface-mounting terminals

Application Examples

- Electronic automatic exchange systems
- Measurement control systems

- Data gathering systems
- Measuring systems

Specifications -

■ Absolute Maximum Ratings (Ta = 25°C)

	Item		Symbol	G3VM-XN(F)	G3VM-4N(F)	Conditions	
Input	LED forward cu	rrent	I _F	30 mA		-	
	Repetitive peak	LED forward current	I _{FP}	1 A		100-μs pulses, 100 pps	
	LED reverse voltage		V _R	5 V		-	
Output			V _{BO}	-60 to 60 V	-400 to 400 V	DC or AC peak value	
	(load voltage)			0 to 60 V	0 to 400 V	DC	
	Continuous	I current		300 mA	150 MA	-	
	load current (see note 1)			450 mA	200 MA		
	(400 11010 1)	C connection		600 mA	300 MA		
Dielectric	strength betwee 2)	n I/O terminals	V _{I-O}	2,500 V AC		1 min	
Ambient temperature		Та	-20 to 85°C		With no icing or condensation		
Storage temperature		Tstg	-55 to 100°C		With no icing or condensation		
Max. sold	lering temperatur	e and time	-	260°C		10 s	

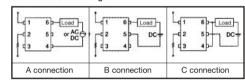
Note: 1. The load current attenuation rates for the different types of connection are as follows:

G3VM-XN(F): A: -3.0 mA/°C; B: -4.5 mA/°C; C: -6.0 mA/°C

G3VM-4N(F): A: -1.5 mA/°C; B: -2.0 mA/°C; C: -3.0 mA/°C

2. The dielectric strength between I/O terminals was measured with voltage applied to all of the LED pins and with voltage applied to all of the light-receiving parts respectively.

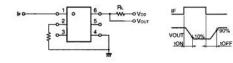
Connection Circuit Diagram



■ Electrical Performance (Ta = 25°C)

	Iten	n	Symbol	G3VM-XN(F)	G3VM-4N(F)	Unit	Conditions	
Input	LED forward current		V _F	1.2 V min, 1.7 V max.		V	I _F = 10 mA	
Trigger LED forward current		I _{FT}	5 mA max.			I _O = 300 mA (G3VM-XN(F)) I _O = 150 mA (G3VM-4N(F))		
Output			R _{ON}	2 Ω max.	12 Ω max.	Ω	I _F = 10 mA	
	resistance	B Connection		1 Ω max.	6 Ω max.		I _O = Max.	
		C Connection		0.5 Ω max. 3 Ω max.				
	Switching cur	rent leakage	I _{LEAK}	1.0 μA max.		μΑ	Voff = 60 V (G3VM-XN(F)) Voff = 400 V (G3VM-4N(F))	
Operate time		T _{ON}	0.5 ms max.	1.0 ms max.	ms	$R_L = 200 \Omega$ (sse note)		
Release t	Release time		T _{OFF}	0.5 ms max. 1.0 ms max.		ms	V _{DD} = 20 V, I _F = 10 mA	
Floating	Floating capacity between I/O terminals			0.8 pF, TYP		pF	f = 1MHz	

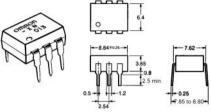
Note: 1. The operate and release time were measured in the way shown below.



Dimensions -

Note: All units are in millimeters unless otherwise indicated.

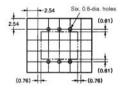
G3VM-XN G3VM-4N



Note: "G3VM" is not printed on the actual product.

■ PCB Dimensions (Bottom View) ■ Actual Mount

G3VM-XN G3VM-4N



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-XNF G3VM-4NF

G3VM-XNF

G3VM-4NF



Note: Mounting pad dimensions shown are top view.

Installation

■ Terminal Arrangement/Internal connection (Top View)

G3VM-XN G3VM-4N



G3VM-XNF G3VM-4NF



Analog-switching MOSFET Relay with Dielectric Strength of 5 kVAC between I/O Using Optical Isolation

- Switches minute analog signals.
- Leakage current of 1 μA max. when output relay is open.

■Application Examples

- · Electronic automatic exchange systems
- ...
- Measurement devices
- · FA systems



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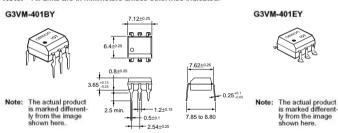
Note: The actual product is marked differently from the image shown here.

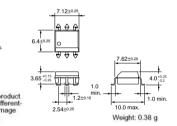
■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	400 VAC	G3VM-401BY	50	
	Surface-mount-		G3VM-401EY		
	ing terminals		G3VM-401EY (TR)		1,500

■ Dimensions

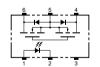
Note: All units are in millimeters unless otherwise indicated.





■Terminal Arrangement/Internal Connections (Top View)

G3VM-401BY

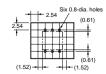


G3VM-401EY



■ PCB Dimensions (Bottom View)

G3VM-401BY



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-401EY

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The actual product is marked differently from the image

■ Absolute Maximum Ratings (Ta = 25°C)

Item			Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		l _F	50	mA	
100 B	Repetitive per current	ak LED forward	1 _{FP}	1	Α	100 µs pulses, 100 pps
	LED forward o	urrent reduction	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse	voltage	V _R	5	٧	
1	Connection temperature		T _i	125	°C	
Output	Output dielectric strength		V _{OFF}	400	V	
	Continuous load current	Connection A	l _O	120	mA	
		Connection B		120		
		Connection C		240		
1	ON current	Connection A	∆1 _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C
	reduction rate	Connection B		-1.2		
		Connection C		-2.4		
	Connection te	emperature	T _j	125	°C	
	Dielectric strength between input and output (See note 1.) Operating temperature Storage temperature		V _{I-O}	5,000	Vrms	AC for 1 min
Operati			Ta	-40 to +85	°C	With no icing or condensation
Storage			T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)				260	°C	10 s

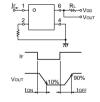
Note:	1.	The dielectric strength between the input an output was checked by applying voltage be tween all pins as a group on the LED side an
		all nins as a group on the light-receiving side

Connection D	iagram
Connection A	1 6 - Load 2 5 p or AC O
Connection B	2 5 DC
Connection C	2 5 DC 7

■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	LED forward voltage		1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current		I _R			10	μA	V _R = 5 V
	Capacity between terr	minals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current		l _{FT}	-		3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	Connection A	R _{ON}		17	35	Ω	I _F = 5 mA, I _O = 120 mA
		Connection B		-	11	20	Ω	I _F = 5 mA, I _O = 120 mA
		Connection C		-	6	10	Ω	I _F = 5 mA, I _O = 240 mA
	Current leakage when the relay is open		LEAK		-	1.0	μА	V _{OFF} = 400 V
Capacity between I/O terminals		CI-O		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		RI-O	1,000		-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%	
Turn-ON time		tON		0.3	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$	
Turn-OFF time			tOFF	***	0.1	1.0	ms	V _{DD} = 20 V (See note 2.)





■ Recommended Operating Conditions

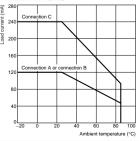
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}	-		320	V
Operating LED forward current	I _F	5	7.5	25	mA
Continuous load current	lo	-6		120	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-401BY(EY)



Analog-switching MOSFET Relay with a Dielectric Strength of 5 kVAC between I/O Using Optical Isolation

- Switches minute analog signals.
- Switching AC and DC.
- Peak load voltage of 600 V.
- Dielectric strength of 5 kVAC between I/O.

■Application Examples

- · Electronic automatic exchange systems
- · FA systems
- · Measurement devices
- · Security systems

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	600 VAC	G3VM-601BY	50	
	Surface-mounting		G3VM-601EY	1	
	terminals	, .	G3VM-601EY(TR)		1,500

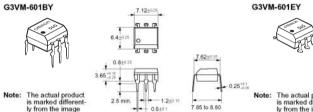
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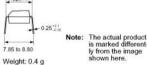
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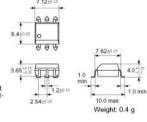
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■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



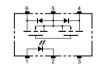




■ Terminal Arrangement/Internal Connections (Top View)

- 2.54±025

G3VM-601BY

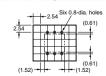


G3VM-601EY



■PCB Dimensions (Bottom View)

G3VM-601BY



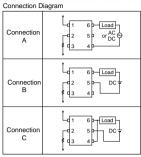
■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-601EY



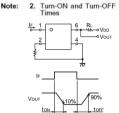
Input I ED forward current			Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		l _F	50	mA	
	Repetitive per current	ak LED forward	1 _{EP}	1	A	100 µs pulses, 100 pps
	LED forward c	urrent reduction	ΔIpPC	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse	voltage	V _R	5	٧	
	Connection temperature		T _j	125	°C	
Output	Output dielectric strength		V _{OFF}	600	V	
	Continuous load current	Connection A	lo	100	mA	
		Connection B		100		
		Connection C		200		
	ON current	Connection A	∆ low/°C	-1.0	mA/°C	Ta≥25°C
	reduction rate	Connection B		-1.0		A Province Ballion of
	0000000	Connection C	1. 1	-2.0	1	
	Connection te	mperature	Tj	125	°C	
Dielectr output (electric strength between input and put (See note 1.) erating temperature		V _{I-O}	5,000	Vrms	AC for 1 min
Operation			Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation	
Solderin	ig temperature	(10 s)		260	°C	10 s

The dielectric strength between the input and output was checked by applying voltage be-tween all pins as a group on the LED side and all pins as a group on the light-receiving side.



■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage		VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current		I _R		-	10	μА	V _R = 5 V
	Capacity between terr	ninals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward o	urrent	l _{FT}	***	1.6	5	mA	I _O = 100 mA
Output	Maximum resistance with output ON	Connection A	R _{ON}	1 777 .	25	35	Ω	I _F = 10 mA, I _O = 100 mA
					30	45	Ω	I _F = 10 mA, I _O = 100 mA
		Connection B		***	23	35	Ω	I _F = 10 mA, I _O = 100 mA
		Connection C			12	18	Ω	I _F = 10 mA. I _O = 200 mA
	Current leakage when open	Current leakage when the relay is open			-	1.0	μА	V _{OFF} = 600 V
Capacity between I/O terminals		C _{1-O}		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		R _{I-O}	1,000	***	-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%	
Turn-ON time		tON		0.2	1.5	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$	
Tum-OF	Turn-OFF time			***	0.2	1.0	ms	V _{DD} = 20 V (See note 2.



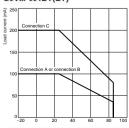
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}	-		480	V
Operating LED forward current	l _F	7.5	15	25	mA
Continuous load current	I _O			100	mA
Operating temperature	Ta	- 20	222	65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-601BY(EY)



Switches Minute Signals and Analog Signals, 6-pin SOP Package and 60-V Load Voltage

- Continuous load current of 400 mA.
- Dielectric strength of 1,500 Vrms between I/O.

Note: The actual product is marked differently from the image shown here.

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- · Amusement machines

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	60 VAC	G3VM-61H1	75	
	terminals	33.0	G3VM-61H1(TR)		2,500

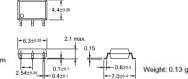
■ Dimensions

Note: All units are in millimeters unless otherwise indicated

G3VM-61H1



Note: The actual product is marked differently from



■ Terminal Arrangement/Internal Connections (Top View)

G3VM-61H1



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-61H1



	ltem		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		l _F	50	mA	
	Repetitive per current	ak LED forward	I _{FP}	1.	Α	100 µs pulses, 100 pps
	LED forward o	urrent reduction	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse	voltage	VR	5	V	
	Connection temperature		Tj	125	"C	
Output	Output dielectric strength		VoFF	60	V	
	Continuous load current	Connection A	I _O	400	mA	
		Connection B		400		
		Connection C		800		
	ON current	Connection A	∆ lon/°C	-4.0	mA/°C	Ta≥25°C
	reduction rate	Connection B		-4.0		
		Connection C	1	-8.0		
	Connection te	mperature	Tj	125	°C	
Dielectric strength between input and output (See note 1.)			V _{I-O}	1,500	Vrms	AC for 1 min
Operating temperature			Ta	-40 to +85	°C	With no icing or condensatio
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensatio	
Soldering temperature (10 s)				260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

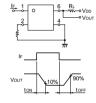
Connection Diagram

CONTICCTION E	g
Connection A	1 6 b Load 2 5 0 or AC 3 4 p
Connection B	2 5 DC
Connection C	1 6 b Load DC T

■ Electrical Characteristics (Ta = 25°C)

Input LED forward voltage			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	LED forward voltage		1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current		I _R			10	μA	V _R = 5 V
	Capacity between terr	minals	CT	***	30	***	pF	V = 0, f = 1 MHz
	Trigger LED forward o	urrent	l _{FT}		1.6	3	mA	I _O = 400 mA
Output	Maximum resistance with output ON	Connection A	R _{ON}		1	2	Ω	I _F = 5 mA, I _O = 400 mA
		Connection B			0.5	1	Ω	I _F = 5 mA, I _O = 400 mA
		Connection C		_	0.25	-	Ω	I _F = 5 mA, I _O = 800 mA
	Current leakage when the relay is open		ILEAK	-	-	1.0	μΑ	V _{OFF} = 60 V
Capacit	y between I/O terminals		Ci-o		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance			R _{i-O}	1,000		-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time			tON		0.8	2.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Tum-OFF time			tOFF		0.1	0.5	ms	V _{DD} = 20 V (See note 2.)

Note: 2. Turn-ON and Turn-OFF



■ Recommended Operating Conditions

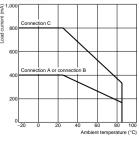
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}		1-	48	V
Operating LED forward current	l _F	5	7.5	25	mA
Continuous load current	lo			400	mA
Operating temperature	Ta	- 20	_	65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-61H1



Slim, 2.1-mm High, MOSFET Relay with Miniature, Flat, 6-pin SOP Package

- New models with 6-pin SOP package now available in the 200-V load voltage series.
- Continuous load current of 200 mA.
- Dielectric strength of 1,500 Vrms between I/O.



Note: The actual product is marked differently from the image

NEW 91

■Application Examples

- · Broadband systems
- · Measurement devices
- Data loggers
- · Amusement machines

■List of Models

Contact form	form Terminals Load voltage (peak value)		Model	Number per stick	Number per tape	
SPST-NO	Surface-mounting	200 VAC	G3VM-201H1	75		
	terminals		G3VM-201H1(TR)		2,500	

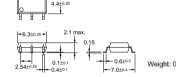
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-201H1



Note: The actual product is marked differently



■Terminal Arrangement/Internal Connections (Top View)

G3VM-201H1



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-201H1



			Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		l _F	50	mA	
	Repetitive per current	ak LED forward	IFP	1	А	100 μs pulses, 100 pps
	LED forward o	urrent reduction	ΔI _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse	voltage	VR	5	V	
	Connection temperature		Tj	125	°C	
Output	Output dielectric strength		V _{OFF}	200	V	
	Continuous load current	Connection A	lo	200	mA	
		Connection B		200		
		Connection C		400		
	ON current	Connection A	ΔI _{ON} /°C	-2.0	mA/°C	Ta≥25°C
	reduction rate	Connection B		-2.0		
		Connection C	1	-4.0		
	Connection te	emperature	Tj	125	°C	
Dielectric strength between input and output (See note 1.)			V _{I-O}	1,500	Vrms	AC for 1 min
Operating temperature			Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation	
Soldering temperature (10 s)				260	°C	10 s

Note:	The dielectric strength between the input an output was checked by applying voltage be tween all pins as a group on the LED side an
	all pins as a group on the light-receiving side

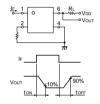
Connection Diagram

	- 0 -
Connection A	1 6 1 Load 2 5 0 or AC O
Connection B	2 5 DC T
Connection C	1 6 P LOAD DC T

■ Electrical Characteristics (Ta = 25°C)

	Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	LED forward voltage		1.0	1,15	1.3	V	I _F = 10 mA
	Reverse current		I _R			10	μА	V _R = 5 V
	Capacity between terr	ninals	CT	***	30		pF	V = 0, f = 1 MHz
	Trigger LED forward o	urrent	l _{FT}		1	3	mA	I _O = 200 mA
Output	Maximum resistance with output ON	Connection A	R _{ON}	-	5	8	Ω	I _F = 5 mA, I _O = 200 mA
		Connection B			3	5	Ω	I _F = 5 mA, I _O = 200 mA
		Connection C			1.5		Ω	I _F = 5 mA, I _O = 400 mA
	Current leakage when the relay is open		ILEAK			1.0	μА	V _{OFF} = 200 V
Capacit	y between I/O terminals	9	CIO		0.8	and .	pF	f = 1 MHz, Vs = 0 V
Insulation resistance			R _{I-O}	1,000		-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Tum-ON time			tON	-	0.6	1.5	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Turn-OFF time			tOFF	228	0.1	1.0	ms	V _{DD} = 20 V (See note 2.)

Note: 2. Turn-ON and Turn-OFF Times



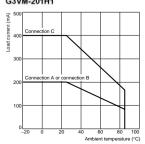
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			160	V
Operating LED forward current	I _F	5	7.5	25	mA
Continuous load current	lo lo			130	mA
Operating temperature	Ta	- 20		60	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-201H1



Slim 2.1mm high relay incorporating a MOSFET Optically Coupled with an Infrared LED in a Miniature, Flat SOP

MOSFET Relay - G3VM-351H

- Upgraded G3VM-S3 Series.
- Continuous load current of 110 mA.
- Dielectric strength of 1,500 Vrms between I/O.

omacon omacon 743

Note: The actual product is marked differently from the image

shown here.

NEW 91

■Application Examples

- · Broadband systems
- · Measurement devices
- Data loggers
- · Amusement machines

■List of Models

Contact form	m Terminals Load voltage (peak value)		Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	350 VAC	G3VM-351H	75	
	terminals		G3VM-351H(TR)	***	2,500

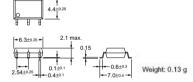
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-351H







■ Terminal Arrangement/Internal Connections (Top View)

G3VM-351H



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-351H



shown here.

■ Absolute Maximum Ratings (Ta = 25°C)

	Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		l _F	50	mA	
	Repetitive per current	ak LED forward	lpp	1	A	100 µs pulses, 100 pps
	LED forward o	urrent reduction	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse	voltage	V _R	5	V	
	Connection temperature		T _j	125	"C	
Output	Output dielectric strength		V _{OFF}	350	V	
	Continuous load current	Connection A	l _O	110	mA	
		Connection B		110		
		Connection C		220		
	ON current	Connection A	∆ lon/FC	-1.1	mA/°C	Ta ≥ 25°C
	reduction rate	Connection B		-1.1		
	2	Connection C	1	-2.2		
	Connection temperature		Tj	125	°C	
Dielectric strength between input and output (See note 1.)			V _{I-O}	1,500	Vrms	AC for 1 min
Operating temperature			Ta	-40 to +85	°C	With no icing or condensation
Storage temperature			T _{stg}	-55 to +125	"C	With no icing or condensation
Soldering temperature (10 s)				260	°C	10 s

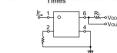
Note:	1.	The dielectric strength between the input ar output was checked by applying voltage b tween all pins as a group on the LED side ar
		all pins as a group on the light-receiving side

Connection Diagram

	Connection Diagram						
Connection A	1 6 1 Load 1 2 5 or AC 0 1 3 4 1						
Connection B	1 6 1 Load 1 DC 1 3 4						
Connection C	1 6 1 Load 1 C T T T T T T T T T T T T T T T T T T						

■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage		VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current		I _R	****		10	μΑ	V _R = 5 V
	Capacity between terr	ninals	CT		30	***	pF	V = 0, f = 1 MHz
	Trigger LED forward o	urrent	l _{FT}		1	3	mA	I _O = 110 mA
Output	Maximum resistance with output ON	Connection A	R _{ON}		25	35	Ω	I _F = 5 mA, I _O = 110 mA, t < 1 s
					35	50	Ω	I _F = 5 mA, I _O = 110 mA
		Connection B			28	40	Ω	I _F = 5 mA, I _O = 110 mA
		Connection C		77U.	14	20	Ω	I _F = 5 mA, I _O = 220 mA
	Current leakage when the relay is open		LEAK		-	1.0	μА	V _{OFF} = 350 V
Capacity between I/O terminals			CI-O		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance			R _{I-O}	1,000			МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time			tON		0.3	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Tum-OF	F time		tOFF		0.1	1.0	ms	V _{DD} = 20 V (See note 2.)



2. Turn-ON and Turn-OFF

■ Recommended Operating Conditions

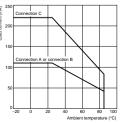
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	I _F	5	10	25	mA
Continuous load current	lo			100	mA
Operating temperature	Ta	- 20	-	65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-351H



with SPST-NC (Single-pole, Single-throw, Normally Closed) Contacts New models in 250 V lead veltage entire with

MOSFET Relay - G3VM-353H

Analog-switching MOS FET Relay

- New models in 350-V load voltage series with SPST-NC contacts and a 6-pin SOP package.
- Continuous load current of 120 mA.
- Dielectric strength of 1,500 Vrms between I/O.



Note: The actual product is marked differently from the image

<u>NEW</u> **91**

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- · Amusement machines

■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NC	Surface-mounting	350 VAC	G3VM-353H	75	
	terminals		G3VM-353H(TR)		2,500

■ Dimensions

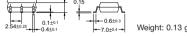
Note: All units are in millimeters unless otherwise indicated.

G3VM-353H





Note: The actual product is marked differently



■ Terminal Arrangement/Internal Connections (Top View)

G3VM-353H



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-353H



	Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		l _F	50	mA	
	Repetitive per current	ak LED forward	1 _{EP}	1	A	100 µs pulses, 100 pps
	LED forward o	urrent reduction	Δ1 _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse	voltage	VR	5	V	
	Connection to	emperature	T _i	125	°C	
Output	Output dielectric strength		V _{OFF}	350	V	
	Continuous load current	Connection A	lo	120	mA	
		Connection B		120		
		Connection C		240		
	ON current	Connection A	A ION/C	-1.2	mA/°C	Ta ≥ 25°C
	reduction rate	Connection B	1 626	-1.2	1	
	500035	Connection C		-2.4	1	
	Connection te	emperature	Ti	125	°C	
Dielectric strength between input and output (See note 1.)		V _{I-O}	1,500	Vrms	AC for 1 min	
Operating temperature			Ta	-40 to +85	PC	With no icing or condensation
Storage temperature			T _{stg}	-55 to +125	"C	With no icing or condensation
Soldering temperature (10 s)				260	°C	10 s

Note:	 The dielectric strength between the input an output was checked by applying voltage be
	tween all pins as a group on the LED side an all pins as a group on the light-receiving side

Connection Diagram

Connection D	iagram
Connection A	1 6 Load 2 5 or AC O
Connection B	41 6 - Load 42 5 - DC
Connection C	1 6 - Load - DC - DC - 3 4 - DC -

■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage		V _F	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current		I _R	***	***	10	μА	V _R = 5 V
	Capacity between terr	minals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward of	urrent	l _{FT}	770	1.0	3.0	mΑ	I _{OFF} = 10 μA
Output	Maximum resistance with output ON	Connection A	R _{ON}	***	15	25	Ω	I _O = 120 mA
		Connection B		***	8	14	Ω	I _O = 120 mA
		Connection C			4		Ω	I _O = 240 mA
	Current leakage when the relay is open		LEAK		-	1.0	μА	V _{OFF} = 350 V, I _F = 5 mA
Capacit	y between I/O terminals		CIO		0.8	-	pF	f = 1 MHz, Vs = 0 V
Insulation resistance			R _{I-O}	1,000		-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time			tON	0 0		1.0	ms	I_F = 5 mA, R_L = 200 Ω ,
Turn-OF	F time		tOFF			3.0	ms	V _{DD} = 20 V (See note 2.





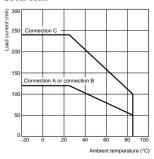
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}	_	-	280	V
Operating LED forward current	I _F	5		25	mA
Continuous load current	I _O			120	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-353H



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Expanded Range of Analog Switching MOSFET Relays with 400-V Load Voltage

- New models with a 6-pin SOP package now included in 400-V load voltage series.
- Continuous load current of 120 mA.
- Dielectric strength of 1,500 Vrms between I/O.



Note: The actual product is marked differently from the image

shown here.

NEW 91

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- Amusement machines

■List of Models

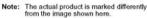
Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	400 VAC	G3VM-401H	75	
	terminals		G3VM-401H(TR)		2,500

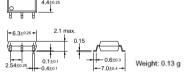
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-401H







■ Terminal Arrangement/Internal Connections (Top View)

G3VM-401H



■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-401H



	Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		l _F	50	mA	
	Repetitive peak LED forward current		Ipp	1	Α	100 μs pulses, 100 pps
	LED forward o	urrent reduction	Δ I _E /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse	voltage	VR	5	V	
	Connection to	emperature	Tj	125	°C	
Output	Output dielectric strength		V _{OFF}	400	V	
	Continuous load current	Connection A	l _o	120	mA	
		Connection B		120		
		Connection C		240		
	ON current	Connection A	Δ I _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C
	reduction rate	Connection B		-1.2		
		Connection C		-2.4		
	Connection to	mperature	Tj	125	°C	
Dielectric strength between input and output (See note 1.)		V _{I-O}	1,500	Vrms	AC for 1 min	
Operating temperature		Ta	-40 to +85	"C	With no icing or condensation	
Storage	temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Solderin	a temperature	(10 s)		260	°C	10 s

Note:	The dielectric strength between the input and output was checked by applying voltage be- tween all pins as a group on the LED side and
	all pins as a group on the light-receiving side.

Connection L	nagram
Connection A	1 6 D Load 2 5 D or AC 3 4 D
Connection B	1 6 b—Load 2 5 DC 7
Connection C	1 6 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1

■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage		VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current		I _R	===	-	10	μА	V _R = 5 V
	Capacity between terr	ninals	CT	***	30		pF	V = 0, f = 1 MHz
	Trigger LED forward o	urrent	l _{FT}		1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	Connection A	RoN		17	35	Ω	I _F = 5 mA, I _O = 120 mA
		Connection B			11	20	Ω	I _F = 5 mA, I _O = 120 mA
		Connection C			6	-	Ω	I _F = 5 mA, I _O = 240 mA
	Current leakage when open	the relay is	LEAK		-	1.0	μΑ	V _{OFF} = 400 V
Capacity between I/O terminals			CI-O		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000	-	-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%	
Tum-ON time			tON		0.3	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Turn-OFF time			tOFF		0.1	1.0	ms	V _{DD} = 20 V (See note 2.)

2. Turn-ON and Turn-OFF

■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}		-	320	V
Operating LED forward current	l _E	5	7.5	25	mA
Continuous load current	lo			120	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-401H

Relays with 2 Output channels. Dielectric Strength of 2.5 kVAC between I/O.

New Analog-switching MOSFET

- Switches minute analog signals.
- Dielectric strength of 2,500 Vrms between I/O.

MOSFET Relay - G3VM-62C1/F1

■ Surface-mounting models included in series.



Note: The actual product is marked differently from the image





■Application Examples

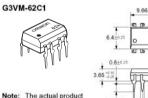
- · Measurement devices
- · Security systems

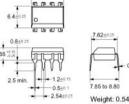
■List of Models

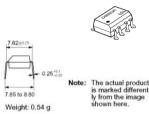
Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NO	PCB terminals	60 VAC	G3VM-62C1	50	
	Surface-mounting	7	G3VM-62F1	1	
	terminals		G3VM-62F1(TR)	222	1,500

■ Dimensions

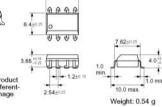
Note: All units are in millimeters unless otherwise indicated.







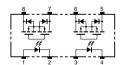
G3VM-62F1

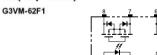


■ Terminal Arrangement/Internal Connections (Top View)

G3VM-62C1

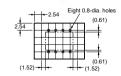
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■PCB Dimensions (Bottom View)

G3VM-62C1



■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-62F1

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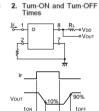
Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	IFP	1	A	100 μs pulses, 100 pps
	LED forward current reduction rate	ΔI _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	V _{OFF}	60	V	
	Continuous load current	lo	500	mA	
	ON current reduction rate	∆ lon/°C	-5.0	mA/°C	Ta ≥ 25°C
	Connection temperature	T _j	125	°C	
	ic strength between input and See note 1.)	V _{I-O}	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

Note:

1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

ltem		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	IR		74	10	μА	V _R = 5 V
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	I _{FT}		1.6	3	mA	I _O = 500 mA
Output	Maximum resistance with output ON	R _{ON}		1.0	2.0	Ω	I _F = 5 mA, I _O = 500 mA
	Current leakage when the relay is open	LEAK			1.0	μА	V _{OFF} = 60 V
Capacity	between I/O terminals	CIO		0.8	***	pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000	-		МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON		0.8	2.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Turn-OFF time		1OFF	***	0.1	0.5	ms	V _{DD} = 20 V (See note 2.)



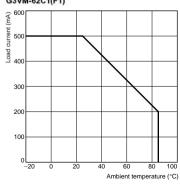
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}		-	48	V
Operating LED forward current	I _F	5	7.5	25	mA
Continuous load current	lo .			500	mA
Operating temperature	Ta	- 20	-	65	°C

■Engineering Data

Load Current vs. Ambient Temperature G3VM-62C1(F1)



New Series with 350-V Load Voltage Including Models with 2 Outputs.

MOSFET Relay - G3VM-352C/F

- Upgraded G3VM-W Series.
- Continuous load current of 120 mA.
- Dielectric strength of 2,500 Vrms between I/O.





■ Application Examples

- · Measurement devices
- · Security systems
- · Amusement machines

Note: The actual product is marked differently from the image

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NO	PCB terminals	350 VAC	G3VM-352C	50	
	Surface-mounting		G3VM-352F	1	
	terminals	5	G3VM-352F(TR)		1,500

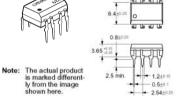
■ Dimensions

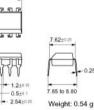
Note: All units are in millimeters unless otherwise indicated.



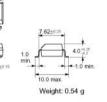
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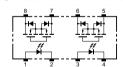






■ Terminal Arrangement/Internal Connections (Top View)

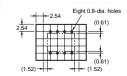
G3VM-352C





■PCB Dimensions (Bottom View)

G3VM-352C



■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-352F

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G3VM-352F



Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	1 _{FP}	1	Α	100 µs pulses, 100 pps
	LED forward current reduction rate	Δ I _E /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	V _{OFF}	350	٧	
	Continuous load current	lo .	120	mA	
	ON current reduction rate	Δ I _{ON} ^r °C	-1.2	mA/°C	Ta ≥ 25°C
	Connection temperature	Tj	125	°C	
	ic strength between input and See note 1.)	V _{I-O}	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	1 _R			10	μА	V _R = 5 V
	Capacity between terminals	CT	775-5	30	-	pF	V = 0, f = 1 MHz
	Trigger LED forward current	I _{FT}		1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	R _{ON}		25	35	Ω	I _F = 5 mA, I _O = 120 mA, t < 1 s
			-	35	50	Ω	I _F = 5 mA, I _O = 120 mA
	Current leakage when the relay is open	ILEAK			1.0	μА	V _{OFF} = 350 V
Capacity	y between I/O terminals	CI-O	22.5	0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000			МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Tum-ON time		tON		0.3	1.0	ms	I_F = 5 mA, R_L = 200 $Ω$,
Turn-OFF time		tOFF		0.1	1.0	ms	V _{DD} = 20 V (See note 2.)

IF 10% 90%

2. Turn-ON and Turn-OFF

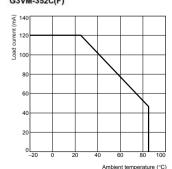
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}		-	280	V
Operating LED forward current	l _F	5	7.5	25	mA
Continuous load current	lo			100	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-352C(F)



New Series with 350-V Load Voltage Current-limiting Models with 2 Outputs.

MOSFET Relay - G3VM-W(F)L

■Application Examples

- · Electronic automatic exchange systems
- · Multi-functional telephones
- · Cordless telephones
- · Measurement devices







Note: The actual product is marked differently from the image shown here.

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Current limit	Number per stick	Number per tape
DPST-NO	PCB terminals	350 VAC	G3VM-WL	Yes	50	-775.0
	Surface-mounting		G3VM-WFL			
	terminals		G3VM-WFL(TR)			1,500

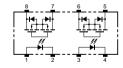
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



■ Terminal Arrangement/Internal Connections (Top View)

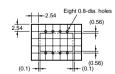
G3VM-WL



8 7 6 5 H4 PH H4 PH

■PCB Dimensions (Bottom View)

G3VM-WL



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-WFL

G3VM-WFL



Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	I _F	50	mA	
	Repetitive peak LED forward current	Ipp	1	А	100 μs pulses, 100 pps
	LED forward current reduction rate	Δ lp/°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	6	V	
	Connection temperature	T _j	125	°C	
Output	Output dielectric strength	V _{OFF}	350	V.	
	Continuous load current	I _O	120	mA	
	ON current reduction rate	∆ low^c	-1.2	mA/°C	Ta ≥ 25°C
	Connection temperature	T _i	125	°C	
Dielectr output (ic strength between input and See note 1.)	VI-O	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)		***	260	°C	10 s

 The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

	ltem		Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	IR			10	μА	V _R = 5 V
	Capacity between terminals	CT		30	***	pF	V = 0, f = 1 MHz
	Trigger LED forward current	I _{FT}	***	1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	RON		22	35	Ω	I _F = 5 mA, I _O = 120 mA
	Current leakage when the relay is open	LEAK	-		1.0	μА	V _{OFF} = 350 V
Limit cu	rrent	ILIM	150	-	300	mA	I _F = 5 mA, V _{DO} = 5 V, t = 5 ms
Capacity	y between I/O terminals	C _{I-O}	***	0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000	-	-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON			1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Turn-OFF time		tOFF			1.0	ms	V ₀₀ = 20 V (See note 2.)

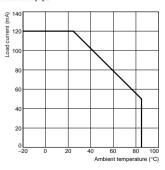
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum U	
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	I _F	5	7.5	25	mA
Continuous load current	lo	1 == 1	==	100	mA
Operating temperature	Ta	- 20		65	°C

■Engineering Data

Load Current vs. Ambient Temperature G3VM-W(F)L



Analog-switching MOSFET Relay with DPST-NC (Double-pole, Single-throw, Normally Closed) Contacts

MOSFET Relay - G3VM-354C/F

- Switches minute analog signals.
- Switching AC and DC.



shown here.



The actual product is marked differently from the image

7

■Application Examples

- · Electronic automatic exchange systems
- · Security systems
- · Datacom (modem) systems
- · FA systems
- Measurement devices

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NC	PCB terminals	350 VAC	G3VM-354C	50	***
	Surface-mounting	1	G3VM-354F	1	
	terminals		G3VM-354F(TR)		1,500

■ Dimensions

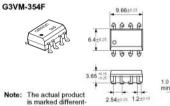
Note: All units are in millimeters unless otherwise indicated.



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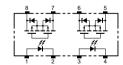


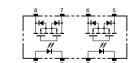


1.0 min. 10.0 max. Weight: 0.54 g

■ Terminal Arrangement/Internal Connections (Top View)

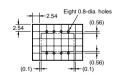
G3VM-354C





■PCB Dimensions (Bottom View)

G3VM-354C



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-354F

G3VM-354F



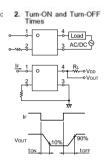
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	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	lp:	50	mA	
	Repetitive peak LED forward current	Ipp	1	A	100 µs pulses, 100 pps
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	٧	
	Connection temperature	T _j	125	°C	
Output	Output dielectric strength	V _{OFF}	350	V	
	Continuous load current	lo	150	mA	
	ON current reduction rate	∆ l _{ON} /°C	-1.5	mA/°C	Ta ≥ 25°C
	Connection temperature	T _j	125	°C	
	ic strength between input and See note 1.)	V _{I-O}	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

ote: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	IR			10	μА	V _R = 5 V
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	l _{ET}	200	1	3	mA	I _{OFF} = 10 μA
Output	Maximum resistance with output ON	RON	 1	15	25	Ω	I _O = 150 mA
	Current leakage when the relay is open	ILEAK			1.0	μА	I _F = 5 mA, V _{OFF} = 350 V
Capacity	y between I/O terminals	C _{1-O}		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000			МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time Turn-OFF time		tON		0.1	1.0	ms	I _F = 5 mA, R _L = 200 Ω,
		tOFF		1.0	3.0	ms	V ₀₀ = 20 V (See note 2.)



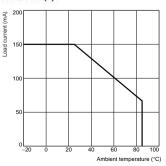
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum U	
Output dielectric strength	V _{DD}		-	280	V
Operating LED forward current	I _F	5		25	mA
Continuous load current	lo		and a	150	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-354C(F)



New MOSFET Relay with Both SPST-NO and SPST-NC Contacts Incorporated in a Single DIP Package

- SPST-NO/SPST-NC models now included in the 350-V load voltage series.
- Continuous load current of 120 mA.
- Dielectric strength of 2,500 Vrms between I/O.





Note: The actual product is marked differently from the image

shown here.

■Application Examples

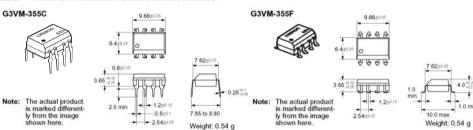
- · Measurement devices
- · Security systems
- Amusement machines

■List of Models

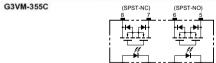
Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO/	PCB terminals	350 VAC	G3VM-355C	50	
SPST-NC	Surface-mounting		G3VM-355F	1	
	terminals		G3VM-355F(TR)		1,500

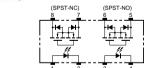
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



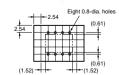
■ Terminal Arrangement/Internal Connections (Top View)





■PCB Dimensions (Bottom View)

G3VM-355C



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-355F

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G3VM-355F



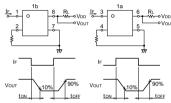
	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	IFP	1	А	100 µs pulses, 100 pps
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	V _{OFF}	350	V	
	Continuous load current	I _O	100	mA	
	ON current reduction rate	∆ l _{ON} ^p C	-1.0	mA/°C	Ta ≥ 25°C
	Connection temperature	T _i	125	"C	
Dielectr output (ic strength between input and See note 1.)	V _{I-O}	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

The dielectric strength between the input and output was checked by applying voltage be-tween all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

	Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward	voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse curr	ent	1 _R			10	μА	V _R = 5 V
	Capacity bety	veen terminals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED 1	orward current	I _{FT}	***	1	3	mA	SPST-NO: I _O = 100 mA
								SPST-NC: I _{OFF} = 10 µA
Out- put	Maximum res output ON	istance with	RON		30	35	Ω	SPST-NO: I _F = 5 mA, I _O = 100 mA
					40	50		SPST-NC: I _F = 0 mA, I _O = 100 mA
	Current leaka relay is open	ge when the	LEAK		-	1.0	μА	V _{OFF} = 350 V
Сарас	city between I/C) terminals	CI-O		0.8		pF	f = 1 MHz, Vs = 0 V
Insula	tion resistance		R _{I-O}	1,000		-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-0	Turn-ON time SPST- NO		tON	-	0.25	1.0	ms	I _F = 5 mA, R _{ij} = 200 Ω V _{DD} = 20 V
		SPST- NC			0.3	1.0	ms	(See note 2.)
NO		SPST- NO	tOFF	-	0.5	1.0	ms	1
		SPST- NC			0.15	1.0	ms	1

2. Turn-ON and Turn-OFF Times



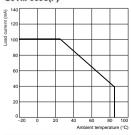
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	l _E	5	10	25	mA
Continuous load current	lo		-	100	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-355C(F)



New Expanded Range of Analog switching MOSFET Relays with 400-V Load Voltage with 2 Output Channels.

- A 2-channel Relay now included in the 400-V load voltage series.
- Continuous load current of 120 mA.
- Dielectric strength of 2,500 Vrms between I/O.



shown here.



Approval pending

Note: The actual product is marked differently from the image

■Application Examples

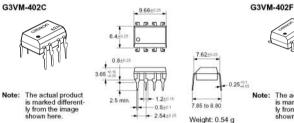
- · Measurement devices
- · Security systems
- · Amusement machines

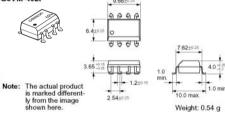
■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NO	PCB terminals	400 VAC	G3VM-402C	50	***
i i	Surface-mounting	1	G3VM-402F		
	terminals		G3VM-402F(TR)		1,500

■ Dimensions

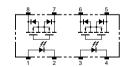
Note: All units are in millimeters unless otherwise indicated.

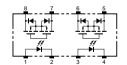




■Terminal Arrangement/Internal Connections (Top View)

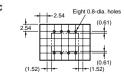
G3VM-402C





■PCB Dimensions (Bottom View)

G3VM-402C



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-402F

G3VM-402F



	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	1 _{EP}	1	Α	100 μs pulses, 100 pps
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	٧	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	VOFF	400	V	
	Continuous load current	I _O	120	mA	
	ON current reduction rate	∆ l _{ON} PC	-1.2	mA/°C	Ta ≥ 25°C
	Connection temperature	T _j	125	°C	
Dielectr output (ic strength between input and See note 1.)	V _{FO}	2,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	IR			10	μА	V _R = 5 V
	Capacity between terminals	CT		30	1770	pF	V = 0, f = 1 MHz
	Trigger LED forward current	l _{ET}	775	1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	R _{ON}		18	35	Ω	I _F = 5 mA, I _O = 120 mA
	Current leakage when the relay is open	ILEAK			1.0	μА	V _{OFF} = 400 V
Capacity	y between I/O terminals	CIO	-	0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		Ri-O	1,000	-	-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON			1.0	ms	I _F = 5 mA, R _L = 200 Ω,
Turn-OFF time		tOFF			1.0	ms	V _{DD} = 20 V (See note 2

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Note: 2. Turn-ON and Turn-OFF

■ Recommended Operating Conditions

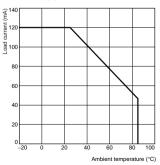
Use the G3VM under the following conditions so that the Relay will operate properly.

ltem	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			320	V
Operating LED forward current	1 _F	5	7.5	25	mA
Continuous load current	lo	-	1 ==	100	mA
Operating temperature	Ta	- 20		65	°C

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■Engineering Data

Load Current vs. Ambient Temperature G3VM-402C(F)



New MOSFET Relay Designed for Switching Minute Signals and Analog Signals. Has 2 Channels and a 60-V Load Voltage

- Continuous load current of 400 mA.
- Dielectric strength of 1,500 Vrms between I/O.



Note: The actual product is marked differently from the image

shown here.

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data Loggers
- · Amusement machines

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NO	Surface-mounting	60 VAC	G3VM-62J1	50	
	terminals		G3VM-62J1(TR)		2,500

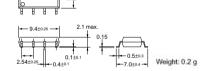
■Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-62J1

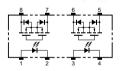


Note: The actual product is marked differently from the image shown here.



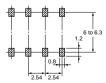
■ Terminal Arrangement/Internal Connections (Top View)

G3VM-62J1



■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-62J1



	ltem	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _E	50	mA	
	Repetitive peak LED forward current	I _{FP}	1	Α	100 µs pulses, 100 pps
	LED forward current reduc- tion rate	∆ I _F P°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	T _i	125	°C	
Output	Output dielectric strength	V _{OFF}	60	V	1
	Continuous load current	10	400	mA	
	ON current reduction rate	∆ lon/°C	-4.0	mA/°C	Ta ≥ 25°C
	ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

Note:

1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	i _F = 10 mA
	Reverse current	IR		***	10	μА	V _R = 5 V
	Capacity between terminals	CT	-	30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	l _{FT}	-	1.6	3	mA	I _O = 400 mA
Output	Maximum resistance with output ON	R _{ON}	-	1.0	2.0	Ω	I _F = 5 mA, I _O = 400 mA
	Current leakage when the relay is open	ILEAK			1.0	μА	V _{OFF} = 60 V
Capacity	y between I/O terminals	C _{1-O}	-	0,8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000	-	-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time Turn-OFF time		tON	-	0.8	2.0	ms	I _F = 5 mA, R _L = 200 Ω,
		tOFF		0.1	0.5	ms	V _{DD} = 20 V (See note 2

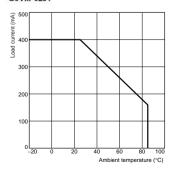
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			48	V
Operating LED forward current	l _E	5	7.5	25	mA
Continuous load current	I _O	-	5 pers	400	mA
Operating temperature	Ta	- 20		65	°C

■Engineering Data

Load Current vs. Ambient Temperature G3VM-62J1



Slim, 2.1-mm High MOSFET Relay with Miniature, Flat, 8-pin SOP Package

- New models with 2 channels and an 8-pin SOP package now available in the 200-V load voltage series.
- Continuous load current of 200 mA.
- Dielectric strength of 1,500 Vrms between I/O.



Note: The actual product is marked differently from the image

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- · Amusement machines

■List of Models

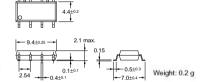
Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NO	Surface-mounting	200 VAC	G3VM-202J1	50	<u></u>
	terminals	300000	G3VM-202J1(TR)	***	2,500

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-202J1

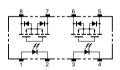




Note: The actual product is marked differently from the image shown here.

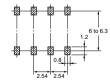
■ Terminal Arrangement/Internal Connections (Top View)

G3VM-202J1



■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-202J1



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■ Absolute Maximum Ratings (Ta = 25°C)

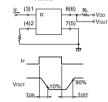
	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	l _{EP}	1	Α	100 µs pulses, 100 pps
	LED forward current reduction rate	Δ1 _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	V _{OFF}	200	V	
	Continuous load current	10	200	mA	
	ON current reduction rate	A IONIOC	-2.0	mA/°C	Ta≥25°C
	ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	I _R			10	μА	V _R = 5 V
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	1 _{FT}	775 cl	1	3	mA	I _O = 200 mA
Output	Maximum resistance with output ON	RON	TE	5	8	Ω	I _F = 5 mA, I _O = 200 mA
	Current leakage when the relay is open	ILEAK			1.0	μА	V _{OFF} = 200 V
Capacity	between I/O terminals	CIO		0.8	-	pF	f = 1 MHz, Vs = 0 V
Insulation resistance		Rio	1,000	-	-	МΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON		0.6	1.5	ms	I _F = 5 mA, R _L = 200 Ω,
Turn-OFF time		tOFF		0.1	1	ms	V _{DD} = 20 V (See note 2

Note: 2. Turn-ON and Turn-OFF



■ Recommended Operating Conditions

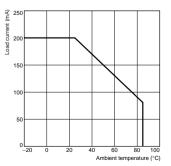
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}		150	200	V
Operating LED forward current	I _F	5	7.5	25	mA
Continuous load current	lo		-	130	mA
Operating temperature	Ta	- 20	-	65	°C

■Engineering Data

Load Current vs. Ambient Temperature

G3VM-202J1



Slim, 2.1-mm High Relay Incorporating a MOSFET Optically Coupled with an Infrared LED in a Miniature, Flat SOP Package

- New models with 2 channels and an 8-pin SOP package included in 350-V load voltage series.
- Continuous load current of 110 mA.
- Dielectric strength of 1,500 Vrms between I/O.

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Note: The actual product is marked differently from the image shown here.

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- · Amusement machines

■List of Models

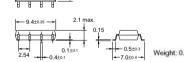
Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NO	Surface-mounting	350 VAC	G3VM-352J	50	
	terminals		G3VM-352J(TR)		2,500

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-352J

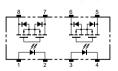




Note: The actual product is marked differently from the image shown here.

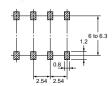
■ Terminal Arrangement/Internal Connections (Top View)

G3VM-352J



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-352J



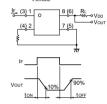
	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	lpp	1	Α	100 μs pulses, 100 pps
	LED forward current reduc- tion rate	Δ1 _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	٧	
	Connection temperature	Tj	125	"C	
Output	Output dielectric strength	V _{OFF}	350	V	
	Continuous load current	lo	110	mA	
	ON current reduction rate	∆ I _{ON} /°C	-1.1	mA/°C	Ta ≥ 25°C
	ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	"C	With no icing or condensation
Solderin	ng temperature (10 s)		260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

ltem		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	IR	***		10	μА	V _R = 5 V
	Capacity between terminals	CT		30	-	pF	V = 0, f = 1 MHz
	Trigger LED forward current	I _{FT}	57354	1	3	mA	I _O = 110 mA
Output	Maximum resistance with output ON	R _{ON}	en:	25	35	Ω	I _F = 5 mA, I _O = 110 mA, t < 1 s
			***	35	50	Ω	I _F = 5 mA, I _O = 110 mA
	Current leakage when the relay is open	LEAK	-	-	1.0	μА	V _{OFF} = 350 V
Capacity	between I/O terminals	CIO	***	0.8	***	pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000	-	-	MΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON	227	0.3	1	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Turn-OF	F time	tOFF	227	0.1	1	ms	V _{DD} = 20 V (See note 2.)

Note: 2. Turn-ON and Turn-OFF



■ Recommended Operating Conditions

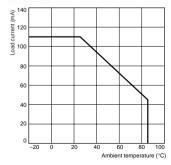
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	l _F	5	10	25	mA
Continuous load current	lo lo			100	mA.
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-352J



Analog-switching MOSFET Relay with DPST-NC (Double-pole, Single-throw, Normally Closed) Contacts

- New models with SPST-NC contacts and an 8-pin SOP package now included in 350-V load voltage series.
- Continuous load current of 120 mA.
- Dielectric strength of 1,500 Vrms between I/O.

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Note: The actual product is marked differently from the image shown here.

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- · Amusement machines

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NC	Surface-mounting	350 VAC	G3VM-354J	50	
	terminals		G3VM-354J(TR)		2,500

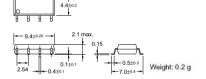
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-354J

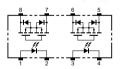


Note: The actual product is marked differently



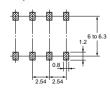
■Terminal Arrangement/Internal Connections (Top View)

G3VM-354J



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-354J



MOSFET Relay - G3VM-355J

■ Absolute Maximum Ratings (Ta = 25°C)

	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _E	50	mA	
	Repetitive peak LED forward current	IfP	.1	А	100 μs pulses, 100 pps
	LED forward current reduction rate	Δ I _E /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	V _{OFF}	350	V	
	Continuous load current	10	120	mA	
	ON current reduction rate	∆ lon/°C	-1.2	mA/°C	Ta ≥ 25°C
	Connection temperature	Tj	125	°C	
	ic strength between input and See note 1.)	VI-O	1,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	"C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	VF	1.0	1.15	1.3	V	I _F = 10 mA
	Reverse current	IR	-		10	μА	V _R = 5 V
	Capacity between terminals	CT	-	30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	IFT		1	3	mA	I _{OFF} = 10 μA
Output	Maximum resistance with output ON	R _{ON}	-	15	25	Ω	I _O = 120 mA
	Current leakage when the relay is open	I _{LEAK}	-		1.0	μА	V _{OFF} = 350 V, I _F = 5 mA
Capacity	between I/O terminals	CIO		0.8		pF	f = 1 MHz, Vs = 0 V
Insulation resistance		R _{I-O}	1,000			МΩ	V _{I-D} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON			1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$
Tum-OFF time		tOFF		***	3.0	ms	V _{DD} = 20 V (See note 2.)

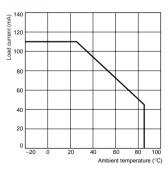
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	I _F	5		25	mA.
Continuous load current	lo			120	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-354J



New MOSFET Relay with Both SPST-NO and SPST-NC Contacts Incorporated in a Single SOP Package

- SPST-NO/SPST-NC models with an 8-pin SOP package now available in the 350-V load voltage series.
- Continuous load current of 120 mA.
- Dielectric strength of 1,500 Vrms between I/O.

omaon 739 NEW SA

Note: The actual product is marked differently from the image

shown here

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- · Amusement machines

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO/	Surface-mounting	350 VAC	G3VM-355J	50	
SPST-NC	terminals		G3VM-355J(TR)		2,500

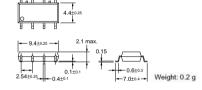
■Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-355J

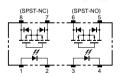


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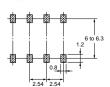
■Terminal Arrangement/Internal Connections (Top View)

G3VM-355J



■Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-355J



	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	l _F	50	mA	
	Repetitive peak LED forward current	l _{EP}	1	Α	100 µs pulses, 100 pps
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	VR	5	V	
	Connection temperature	Tj	125	"C	
Output	Output dielectric strength	V _{OFF}	350	V	
	Continuous load current	l _o	90	mA	
	ON current reduction rate	∆ lovec	-0.9	mA/°C	Ta ≥ 25°C
	Connection temperature	T _i	125	°C	
Dielectric strength between input and output (See note 1.)		V _{I-O}	1,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	"C	With no icing or condensation
Storage temperature		T _{stg}	-55 to +125	"C	With no icing or condensation
Solderin	ng temperature (10 s)		260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

	Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions			
Input	LED forward	voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA			
	Reverse curr	ent	I _R		***	10	μA	V _R = 5 V			
nals	Capacity bety	ween termi-	CT	550	30	(T)	pF	V = 0, f = 1 MHz			
	Trigger LED t	forward cur-	I _{ET}		1	3	mA	SPST-NO: I _O = 90 mA			
			I _{FC}	1							SPST-NC: I _{OFF} = 10 µA
Out- put	Maximum res output ON	sistance with	R _{ON}	-	30	35	Ω	SPST-NO: I _F = 5 mA, I _O = 90 mA			
					40	50		SPST-NC: I _F = 0 mA, I _O = 90 mA			
	Current leaka relay is open	age when the	LEAK	-	-	1.0	μА	V _{OFF} = 350 V			
Capa	city between I/O) terminals	CI-O		0.8		pF	f = 1 MHz, Vs = 0 V			
Insula	tion resistance		R _{FO}	1,000	-	2776	МΩ	V _{I.O} = 500 VDC, RoH ≤ 60%			
Turn-0	ON time	SPST- NO	tON		0.25	1.0	ms	I _F = 5 mA, R _L = 200 Ω, V _{DD} = 20 V (See note 2.)			
		SPST- NC			0.3	1.0	ms	1			
Turn-(OFF time	SPST- NO	tOFF	-	0.5	1.0	ms]			
		SPST- NC			0.15	1.0	ms	1			

2. Turn-ON and Turn-OFF Times

■ Recommended Operating Conditions

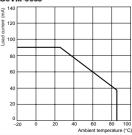
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	l _F	5	10	25	mA
Continuous load current	I _O			90	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-355J



Expanded Range of Analog-Switching MOSFET Relays with 400-**V** Load Voltage

- New models with two channels and an 8-pin SOP package included in 400-V load voltage series.
- Continuous load current of 120 mA.
- Dielectric strength of 1,500 Vrms between I/O.

■Application Examples

- · Broadband systems
- · Measurement devices
- · Data loggers
- · Amusement machines

■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NO	Surface-mounting	400 VAC	G3VM-402J	50	
	terminals		G3VM-402J(TR)	***	2,500

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shown here.

The actual product is marked differently from the image

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NO	Surface-mounting	400 VAC	G3VM-402J	50	
	terminals		G3VM-402J(TR)	***	2,500

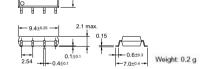
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-402J

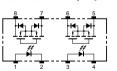


Note: The actual product is marked differently from the image shown here.



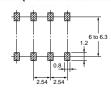
■ Terminal Arrangement/Internal Connections (Top View)

G3VM-402J



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-402J



Item		Symbol	Rating	Unit	Measurement Conditions	
Input	LED forward current	l _F	50	mA		
	Repetitive peak LED forward current	IFP	1	A	100 µs pulses, 100 pps	
	LED forward current reduction rate	Δ1 _F /°C	-0.5	mA/°C	Ta ≥ 25°C	
	LED reverse voltage	VR	5	V		
	Connection temperature	T _i	125	°C		
Output	Output dielectric strength	V _{OFF}	400	V		
	Continuous load current	lo	120	mA		
	ON current reduction rate	∆ I _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C	
Dielectr output (ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min	
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation	
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation	
Soldering temperature (10 s)			260	°C	10 s	

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and

■ Electrical Characteristics (Ta = 25°C)

	Item	Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage	V _F	1.0	1.15	1.3	v	I _F = 10 mA
	Reverse current	IR	***		10	μА	V _R = 5 V
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current	IFT	570	1	3	mA	I _O = 120 mA
Output	Maximum resistance with output ON	Ron	***	17	35	Ω	I _F = 5 mA, I _O = 120 mA
	Current leakage when the relay is open	LEAK			1.0	μА	V _{OFF} = 400 V
Capacity	y between I/O terminals	CIO		0.8		pF	f = 1 MHz, Vs = 0 V
Insulatio	on resistance	R _{I-O}	1,000	-	-	МΩ	V_{I-O} = 500 VDC, RoH \leq 60%
Turn-ON time Turn-OFF time		tON	777	0.3	1	ms	I _F = 10 mA, R _L = 200 Ω,
		tOFF		0.1	1	ms	V _{DD} = 20 V (See note 2.)

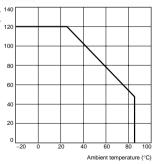
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			320	V
Operating LED forward current	l _F	5	7.5	25	mA
Continuous load current	lo	775	-	120	mA
Operating temperature	Ta	- 20	-	65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-402J



all pins as a group on the light-receiving side.

2. Turn-ON and Turn-OFF



Test Current

■ Glossarv CONTACTS

The contact mechanism of the Relay.

The rated load of the contact of the Relay, which determines the characteristic performance of the contact of the Relay, is expressed by the switching voltage and switching current.

The switching voltage of the Relay determines the characteristic performance of the contact of the Relay. Do not apply voltage that exceeds the maximum switching voltage of the Relay.

The value of the current which can be continuously applied to the

Relay contacts without opening or closing them, which also allows the Relay to stay within the permissible temperature rise

A current which serves as a reference in determining the

performance of the Relay contacts. This value will never exceed

the carry current. When using a Relay, plan not to exceed this

The total resistance of the conductor, which includes specific

resistivities, such as of the armature and terminal, and the

resistance of the contacts. This value is determined by measuring

the voltage drop across the contacts by the allowed test current

 ∴ Ammeter (v) Voltmeter

Power source

(DC or AC)

R: Variable resistor

Number of Contact Poles The number of contact circuits.

Maximum Switching Voltage

Maximum Switching (Contact) Current

Contact Form

Rated Load

Carry Current

value

Contact Resistance

shown in the table below.

Rated current or switched current (A)	Test current (mA)
0.01 or higher but less than 0.1	10
0.1 or higher but less than 1	100
1 or higher	1,000

To measure the contact resistance, a milliohmmeter can also be used, although the accuracy drops slightly.

Contact Symbols

Technical Information – General Purpose Relays

NO contact	NC contact	SPDT contact
-0° 1·L	→	
Double-break NO contact	Double-break NO contact	Make-before- contact contact
<u> </u>	- <u>•</u>	
Wiper contact	Latching Relay contact	Ratchet relay contact
	P R R	

Make-before-break Contact

A contact arrangement in which part of the switching section is shared between both an NO and an NC contact. When the Relay operates or releases, the contact that closes the circuit operates before the contact that opens the circuit releases. Thus both the contacts are closed momentarily at the same time.

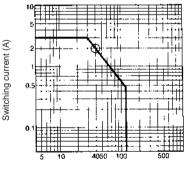
Maximum Switching Power

The maximum capacity value of the load which can be switched without causing problems of material break-down and/or electrical overload. When using a Relay, be careful not to exceed this value. For example, when switching voltage V, is known, max. switching current I, can be obtained at the point of intersection on the characteristic curve "Maximum switching power" below. Conversely, max. switching voltage V, can be operated if I, is

Max. switching current (I1) =

Maximum switching power [W(VA)] Switching voltage (V1)

For instance, if the switching voltage = 40 V, the max. switching current = 2 A (see circled point on graph).



Switching voltage (V)